

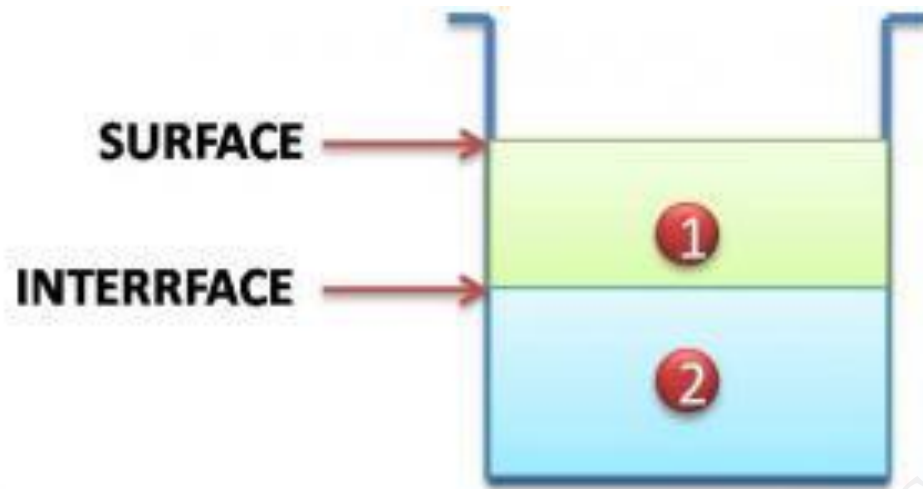
Chương 4. Biến tính bề mặt vật liệu với lớp mỏng các phân tử hữu cơ (T6)

4.1. Biến tính bằng lớp mỏng hữu cơ kích thước nano mét

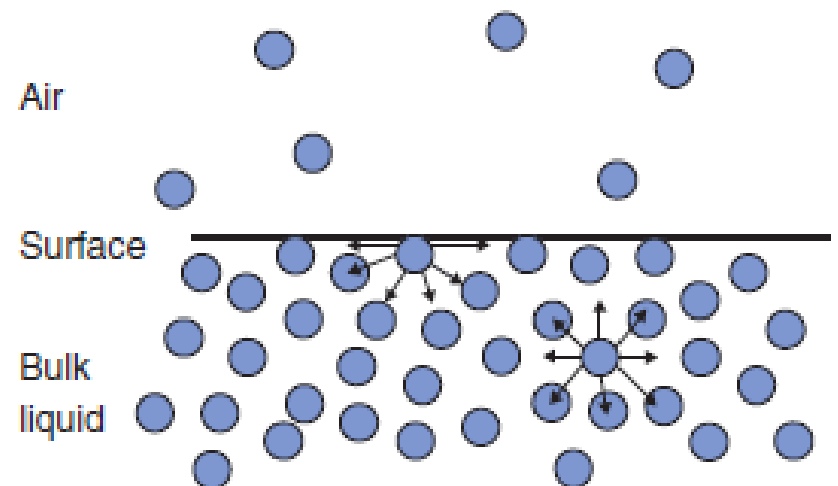
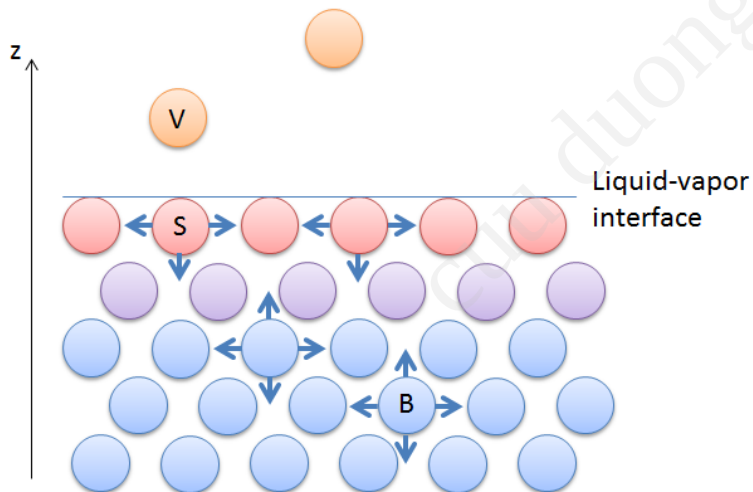
4.2. Biến tính bằng lớp mỏng hữu cơ đa lớp

4.3. Một số tính chất bề mặt của vật liệu biến tính bằng lớp mỏng hữu cơ

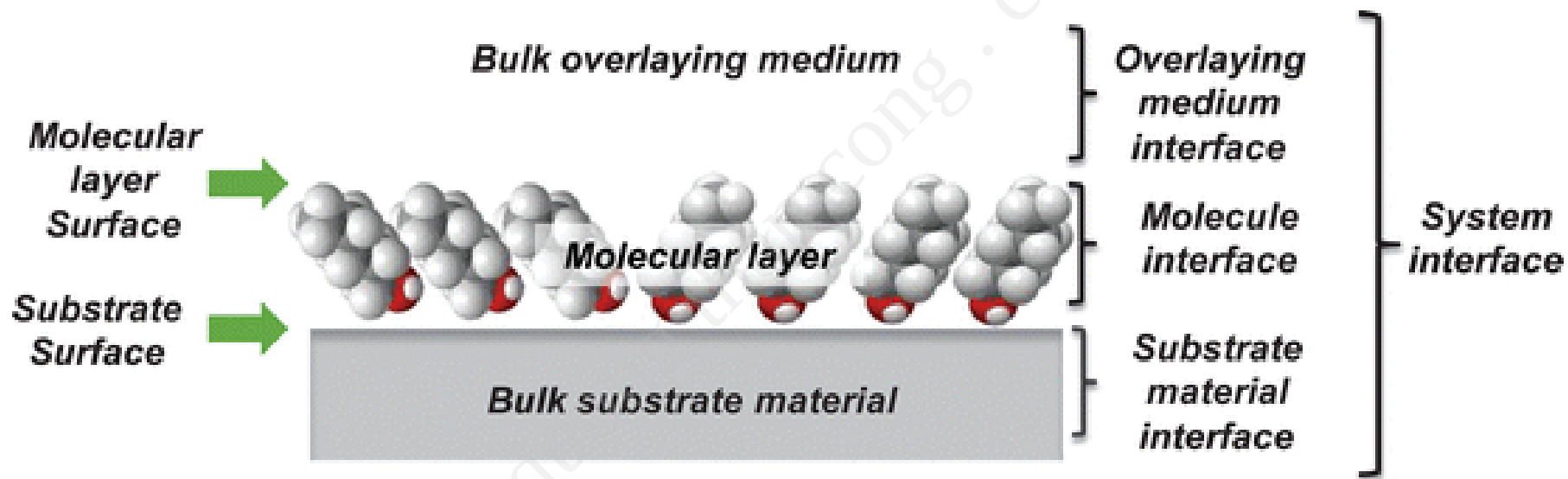
surface and interface



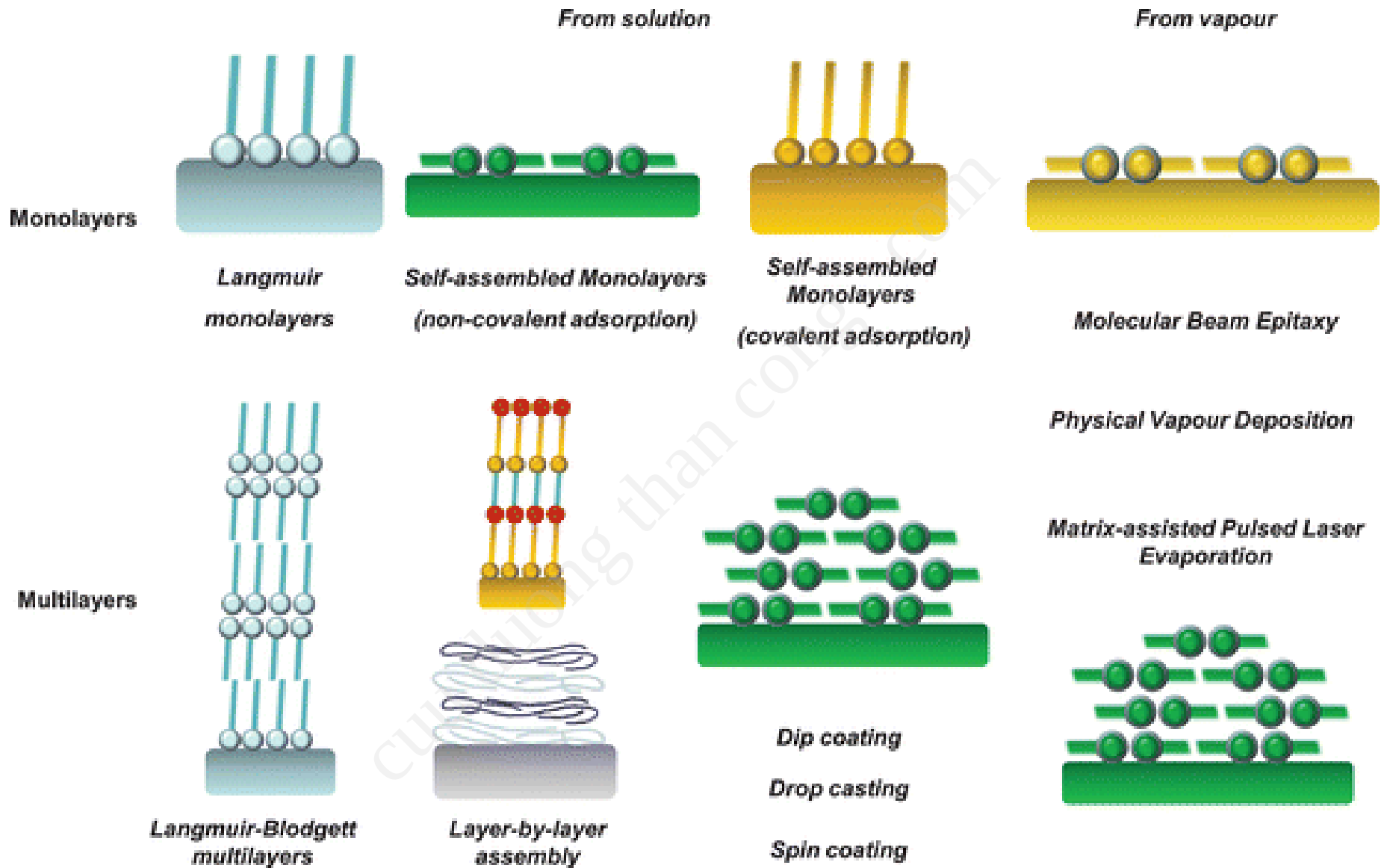
1 & 2 are two different phases



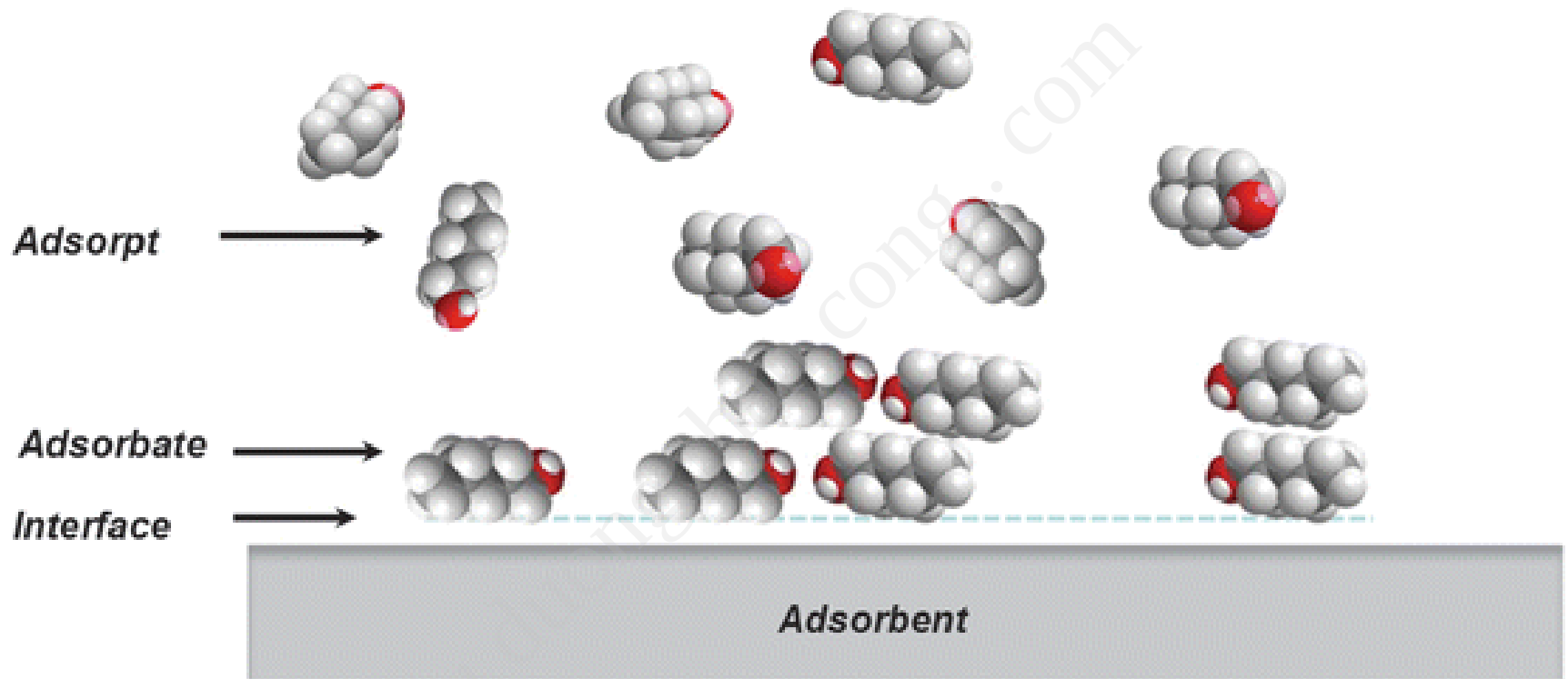
Surfaces for Supramolecular Systems



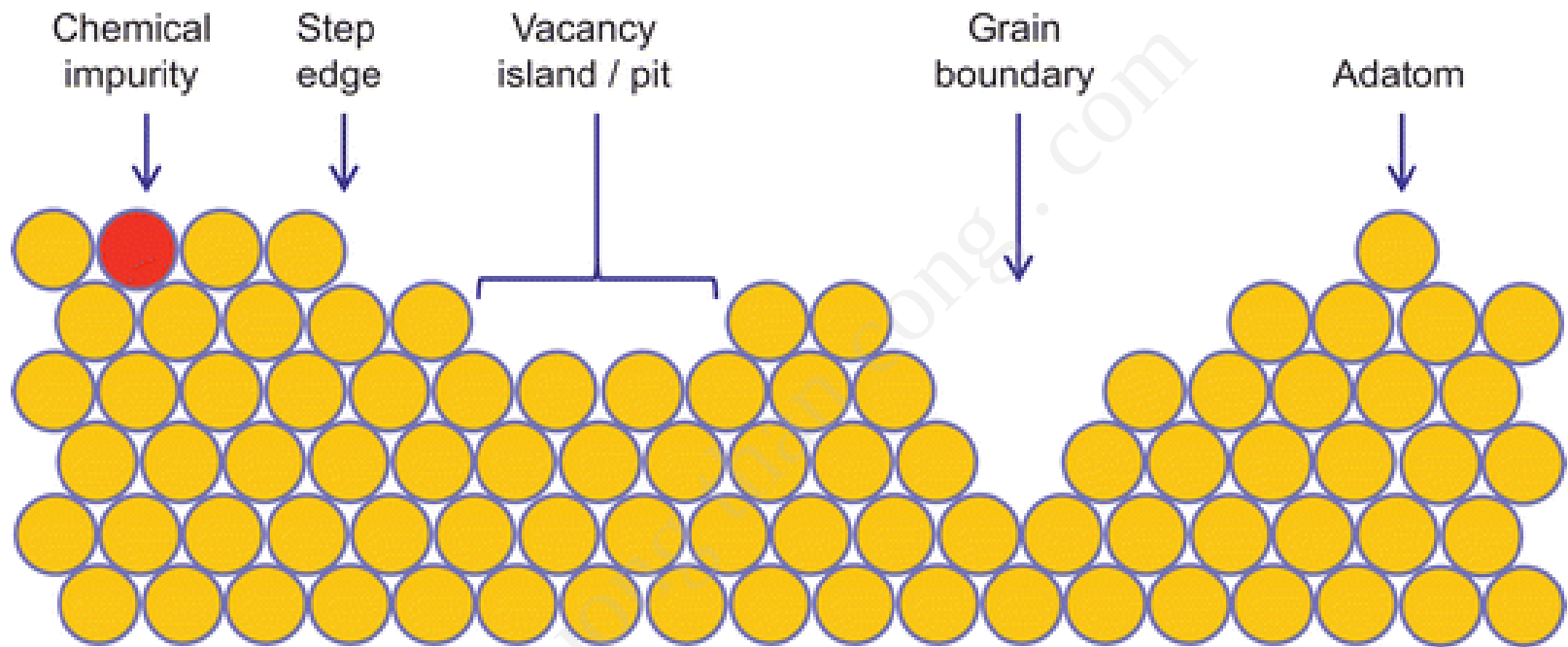
The concepts of surface and interface, of each material and the system.



Some routes to the formation of layers of molecules on surfaces



Adsorption and the definition of the components in the system



Some common surface defects on flat surfaces

early stages of adsorption (low)

Γ

Henry

Conc./ P

monolayer to which the adsorbate has negligible affinity

Γ

Langmuir

Conc./ P

self-assembly can play a role

Γ

Cooperative

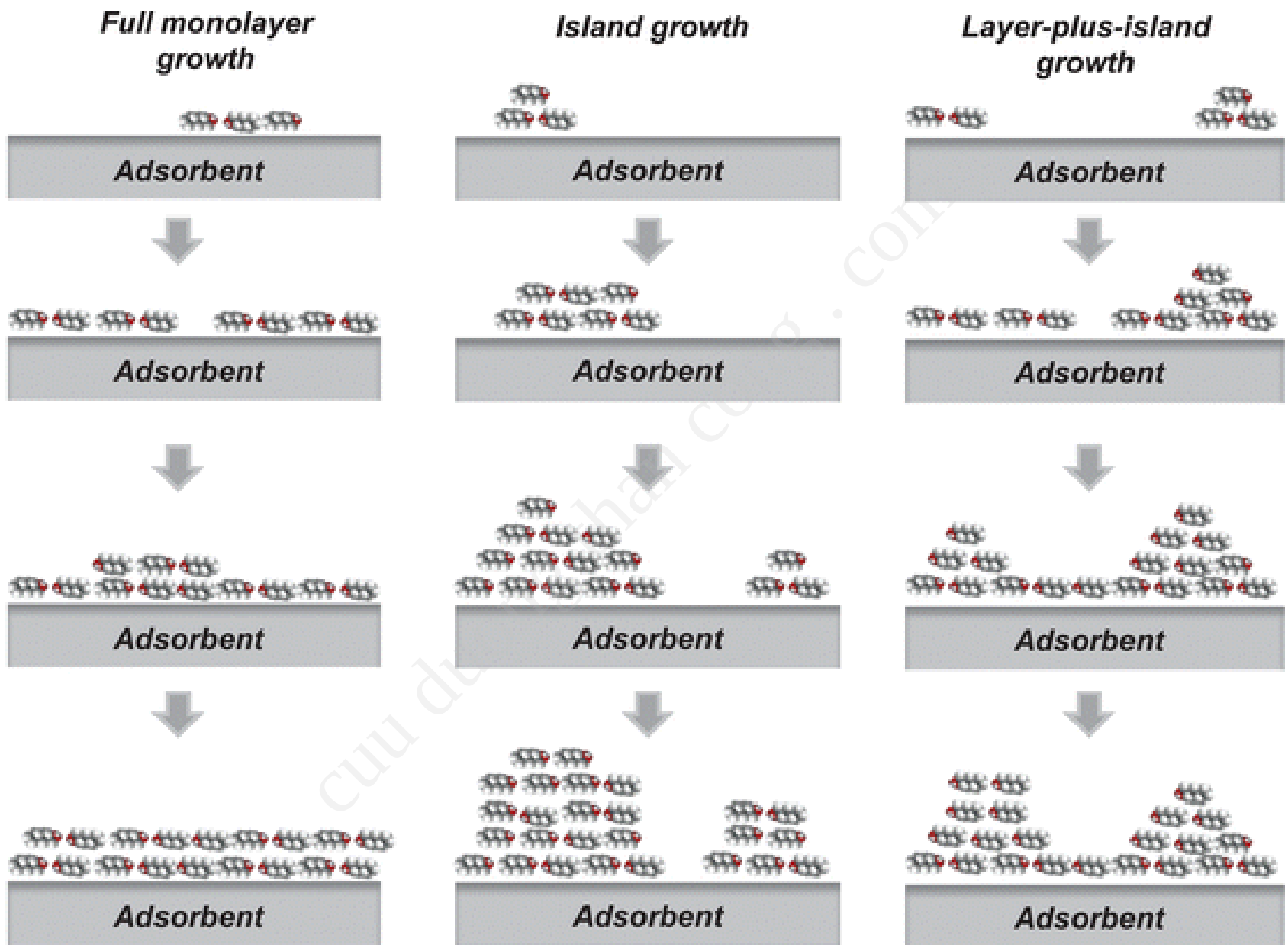
Conc./ P

multilayer adsorption

Γ

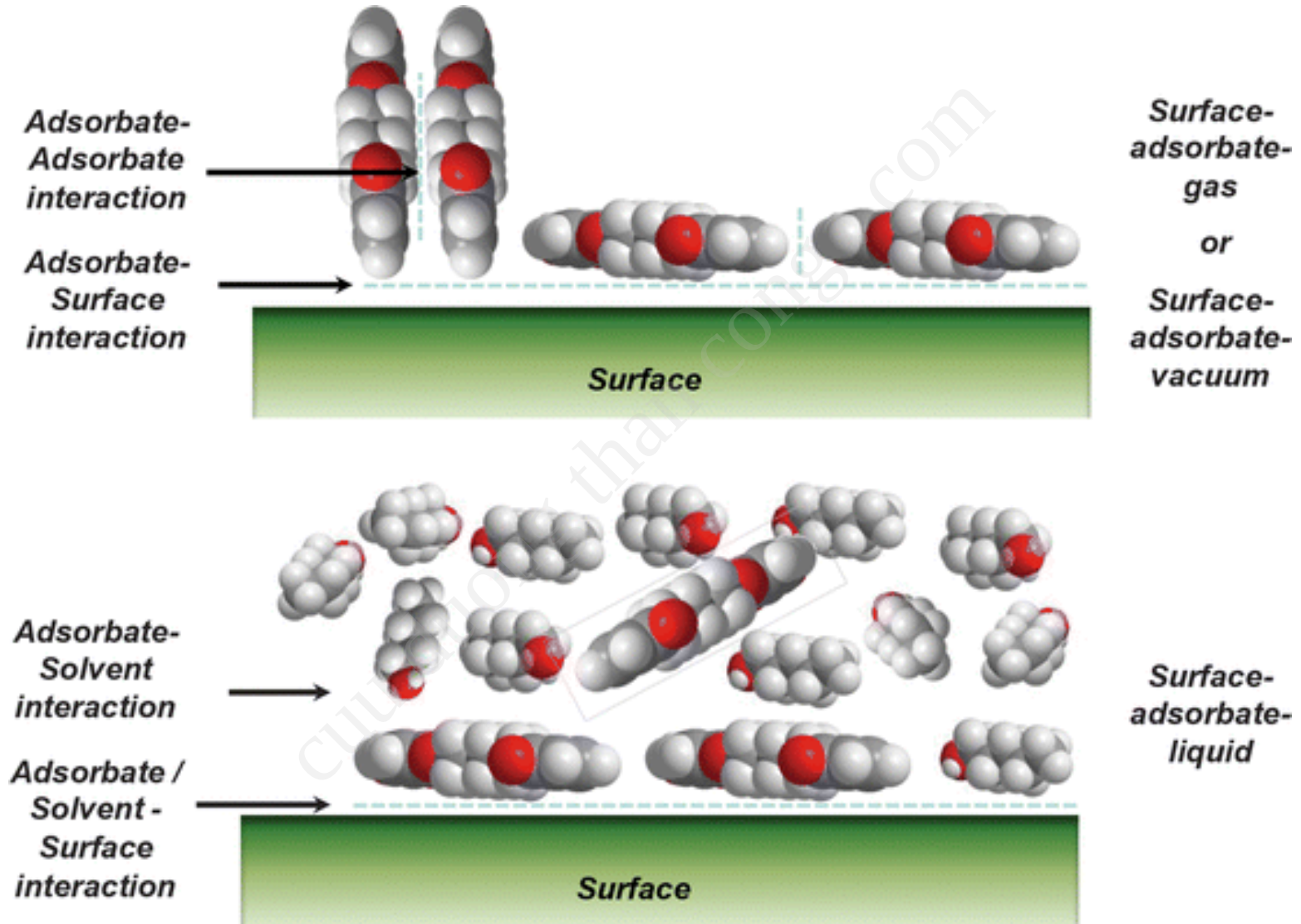
BET

Conc./ P



Three contrasting situations for layer formation on an adsorbent when an adsorpt attaches to it.

strong adsorbate–adsorbate interaction (compared with adsorbate–adsorbent) can lead to a perpendicular arrangement of the molecules



surface–adsorbate interaction dominates, then the molecules will lay coplanar to the surface

Physisorption

Weak adsorbate-adsorbent bond

Close to equilibrium

Reversible

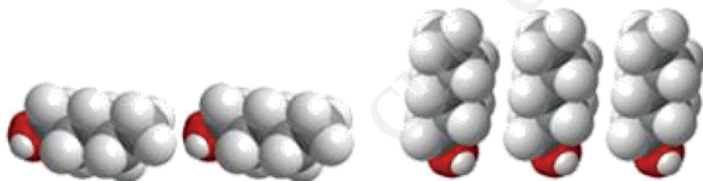
Desorption-re-adsorption possible

On-surface diffusion at low coverage

Adsorbate orientation often specific and usually parallel to surface

Partial layer relatively labile

Often all-or-nothing layers (cooperativity) with quite large domains



Chemisorption

Strong adsorbate-adsorbent bond

Far from equilibrium

Not reversible

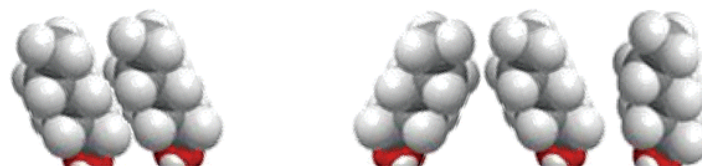
Adsorbate linked to surface

No diffusion once attached

Adsorbate orientation variable and usually quasi-perpendicular to surface

Partial layer stable

Full layers possible with relatively small domains



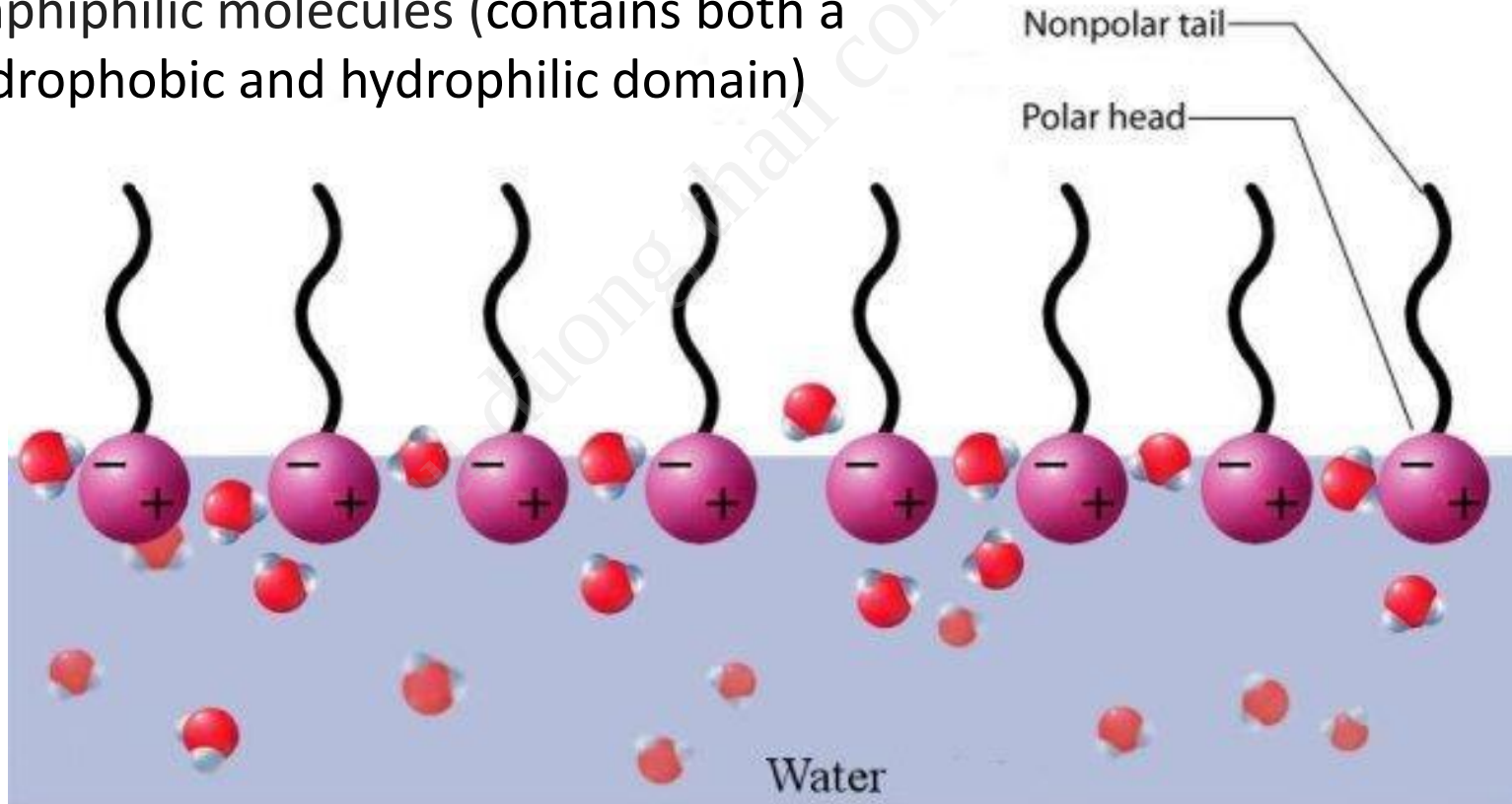
Adsorbent

Some general characteristics of physisorbed and chemisorbed monolayers.

Dr. Irving Langmuir (1917): Single water-surface monolayers could be transferred to solid substrates

Dr. Katharine Blodgett (1935): several of these single monolayer films could be stacked on top of one another to make multilayer films

amphiphilic molecules (contains both a hydrophobic and hydrophilic domain)



Langmuir-Blodgett Layers (LB layers)

Early in the 20th century, Irving Langmuir and Katherine Blodgett founded the science of **Langmuir-Blodgett** films by examining the transfer of Langmuir monolayers onto substrates.



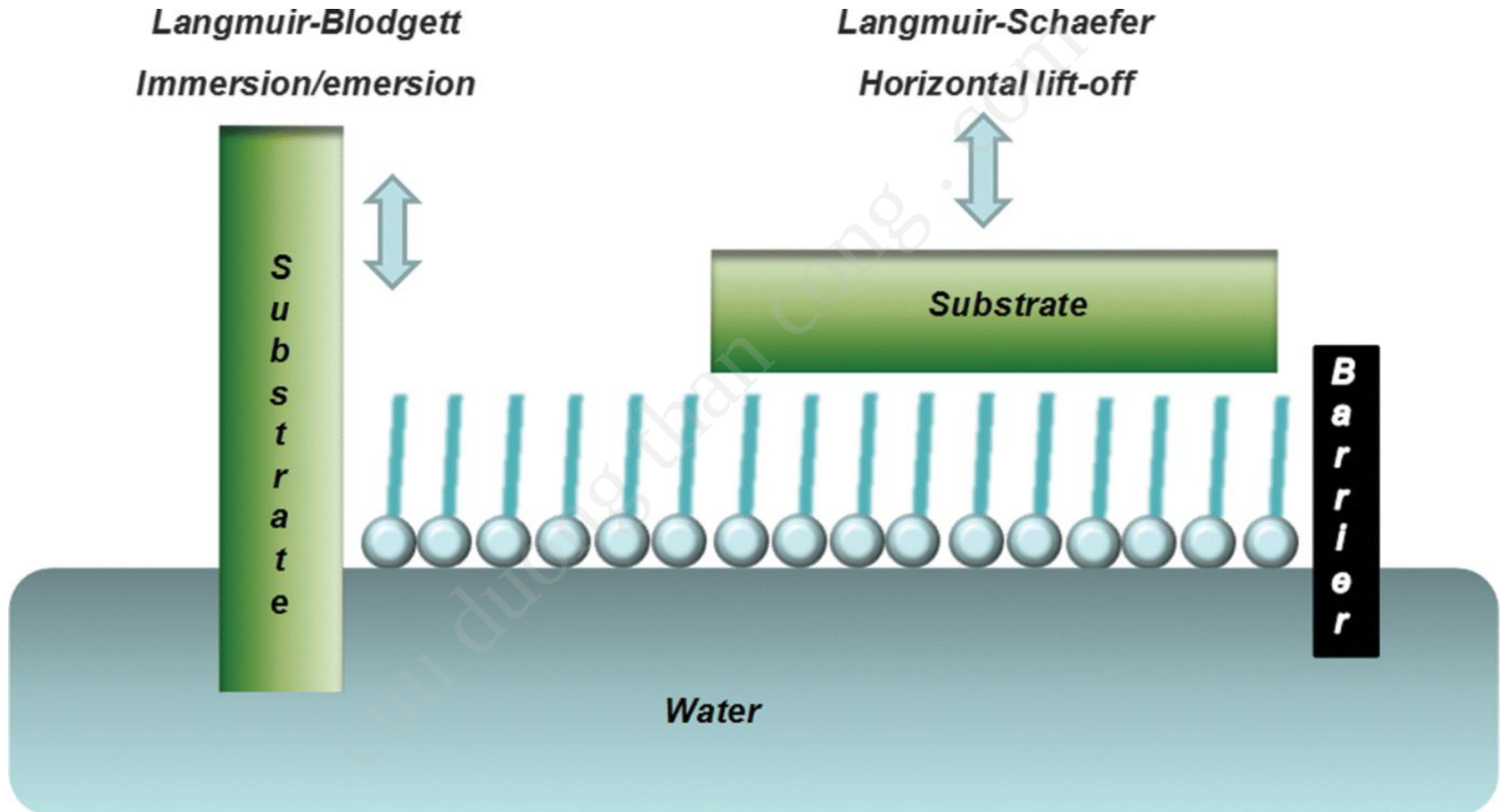
General Electric



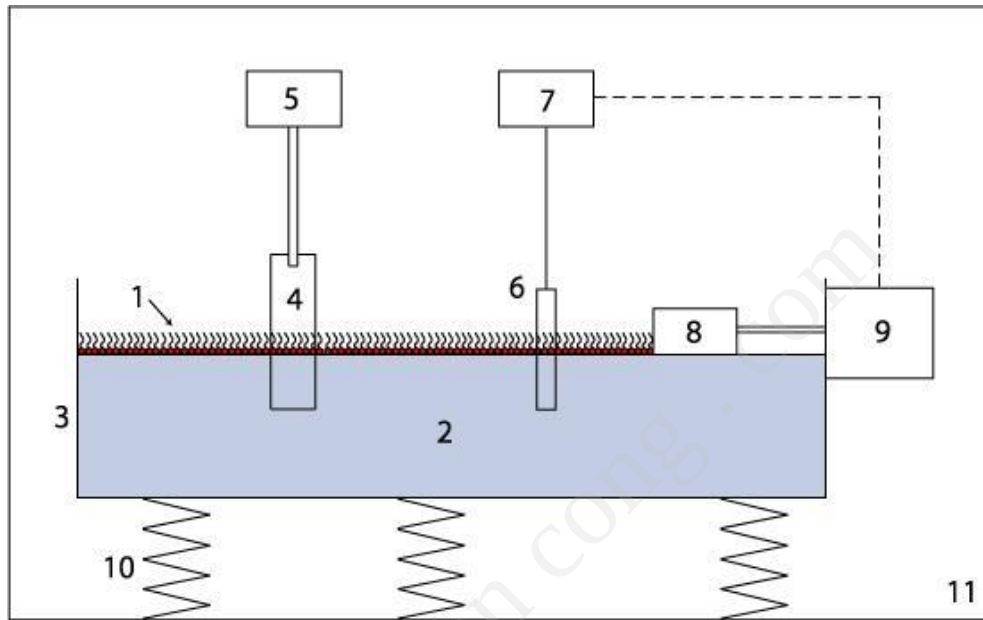
Irving Langmuir (1881 – 1957)
American chemist and
physicist, 1932 Nobel Prize in
Chemistry in surface chemistry

Katharine Burr Blodgett (1898 –1979)
American scientific researcher
Film structure and method of preparation
US 2220860 A

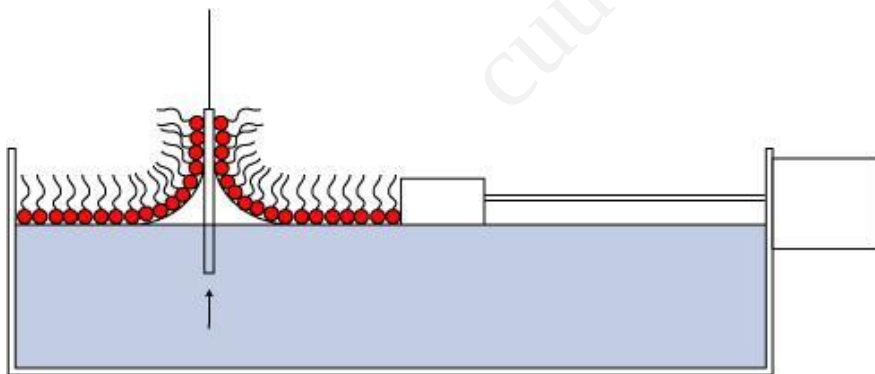
Assembly at the Surface of Liquids



The methods used to transfer Langmuir layers onto solid substrates, by dipping the solid substrate into the trough (the Langmuir–Blodgett method) or by contacting the solid parallel to the air–water interface (Langmuir–Schaefer, or horizontal lift-off method).

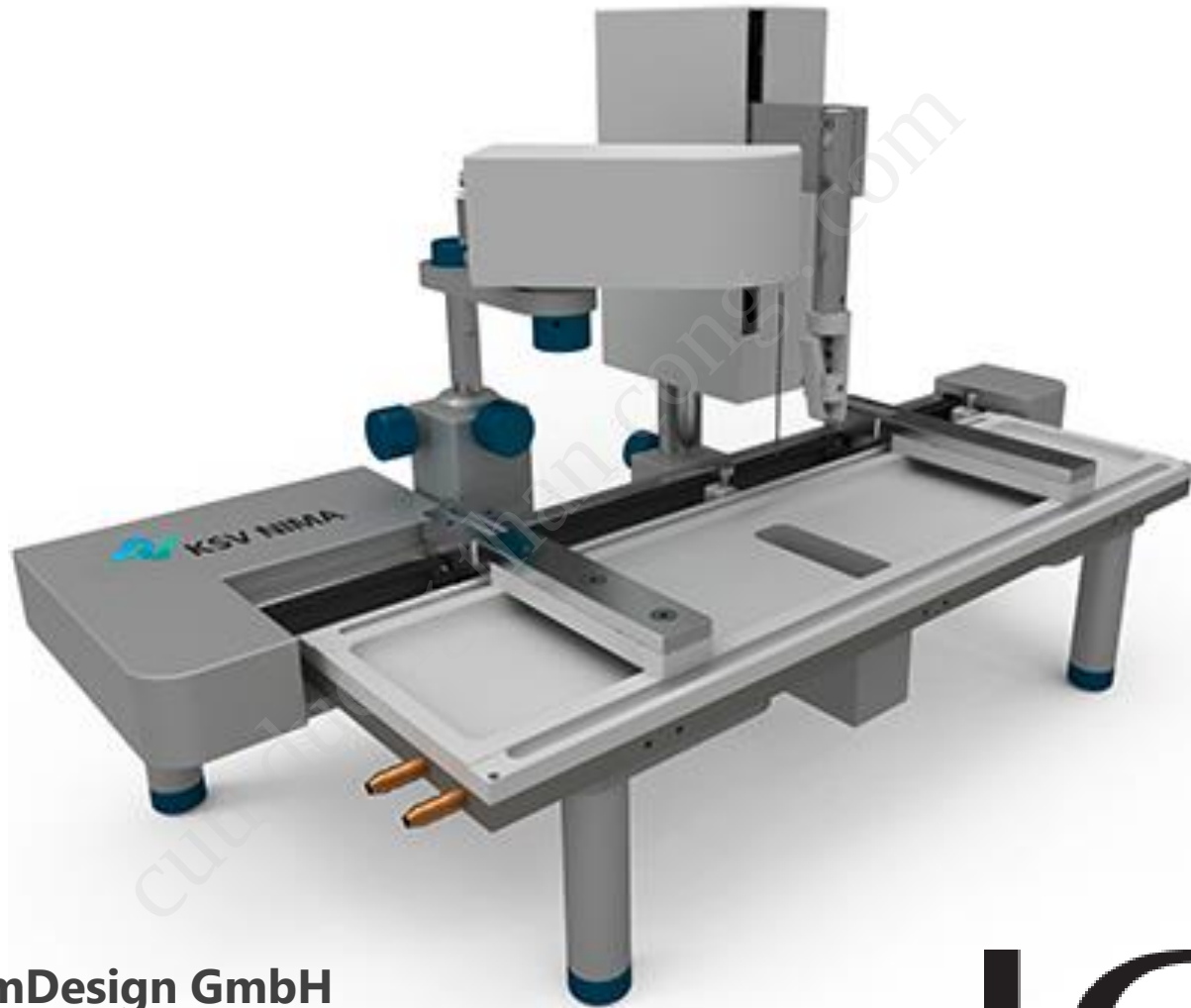


A schematic of a Langmuir Blodgett trough: 1. Amphiphile monolayer 2. Liquid subphase 3. LB Trough 4. Solid substrate 5. Dipping mechanism 6. Wilhelmy Plate 7. Electrobalance 8. Barrier 9. Barrier Mechanism 10. Vibration reduction system 11. Clean room enclosure



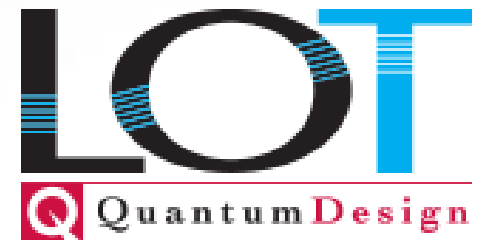
monolayer transfer onto a substrate after film compression. The substrate is moving from bottom to top and is hydrophilically coated since the polar head groups are adhering to the surface

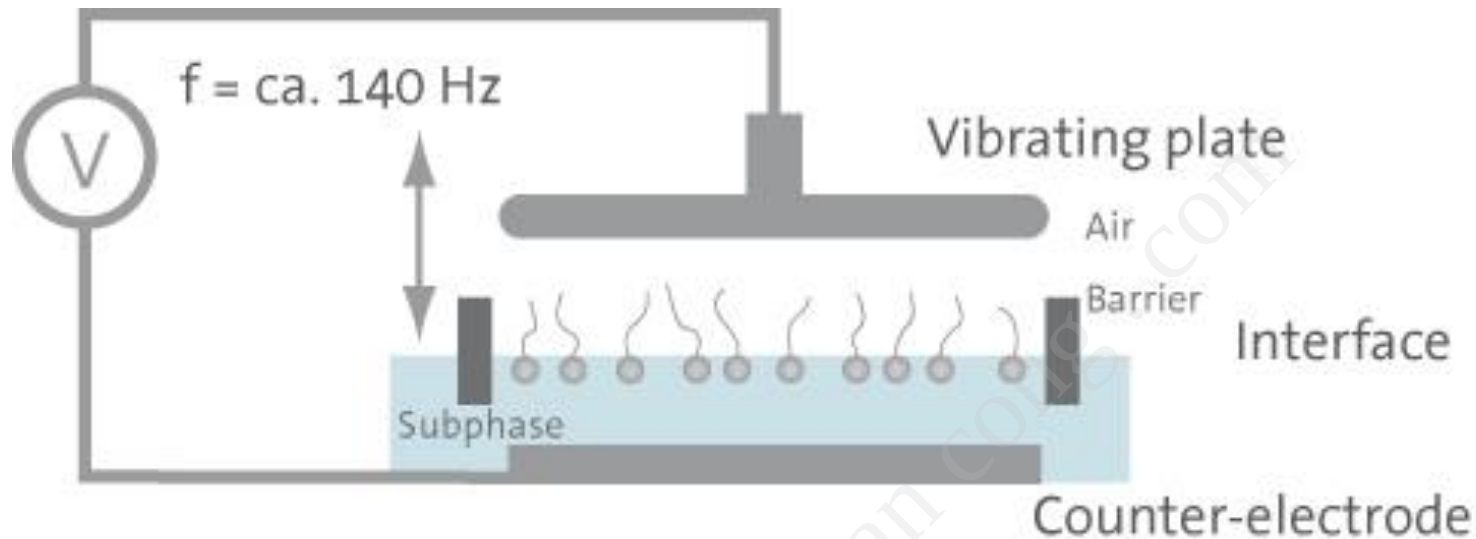
Langmuir and Langmuir-Blodgett troughs



LOT-QuantumDesign GmbH

Im Tiefen See 58
64293 Darmstadt
Germany





$$\Delta V = \mu_n / \epsilon \cdot \epsilon_0 \cdot A$$

with

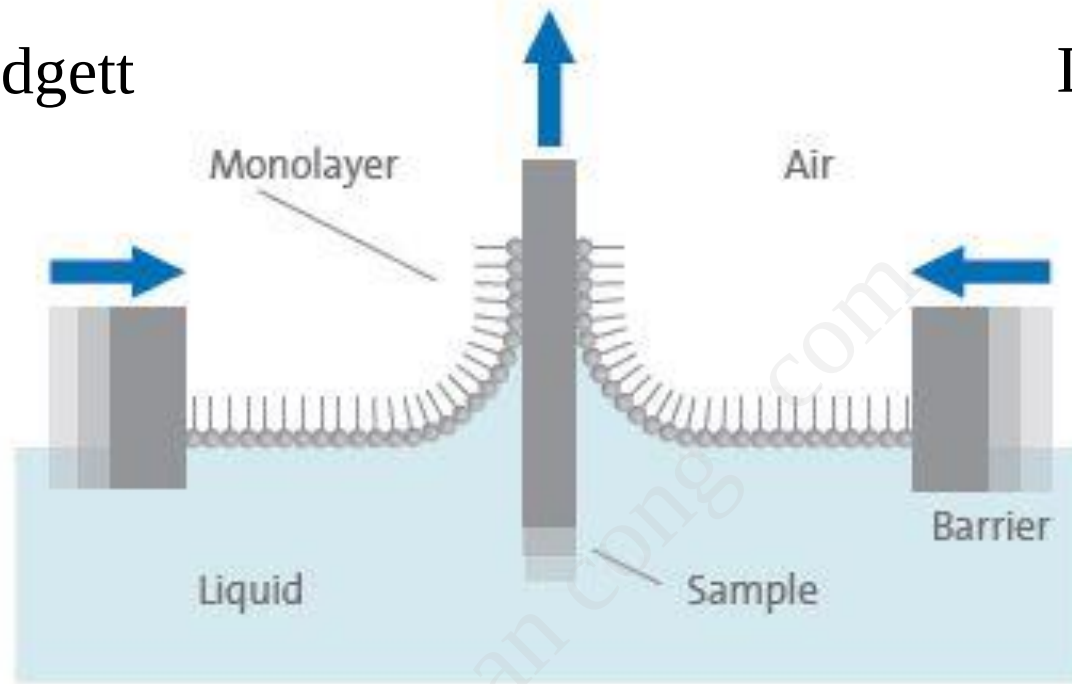
ϵ = subphase permittivity (e.g. here water)

ϵ_0 = air permittivity

A = area per molecule

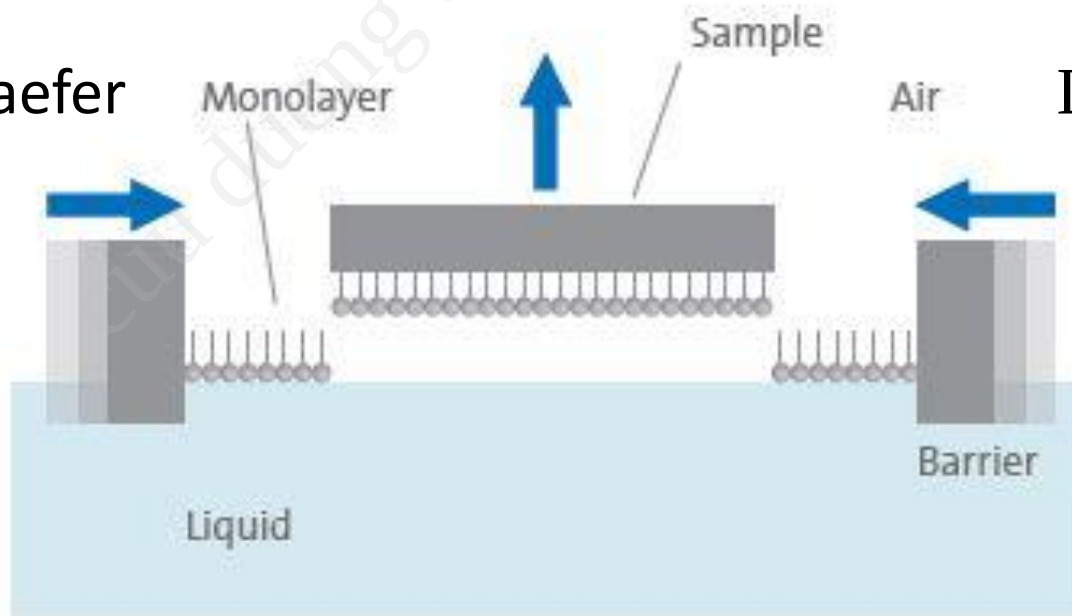
μ_n = vertical component of the dipole moment

Langmuir–Blodgett method



LB method

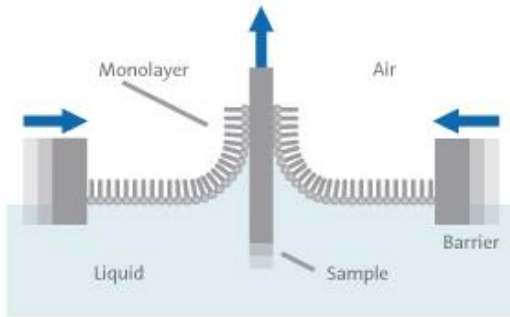
Langmuir–Schaefer method



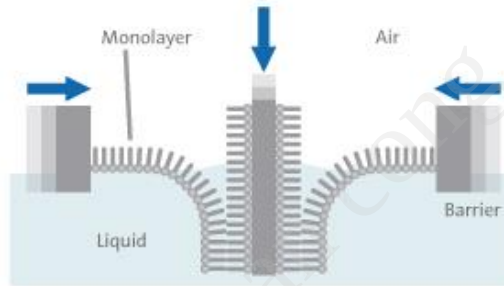
LS method

The density, thickness and homogeneity properties of the monolayers are preserved when transferring the Langmuir film. This gives the possibility to make organized multilayer structures with varying layer compositions.

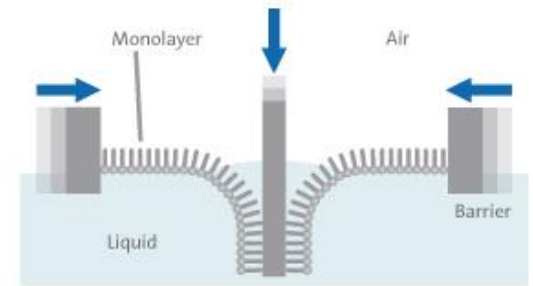
LB DEPOSITION ON A HYDROPHILIC SURFACE



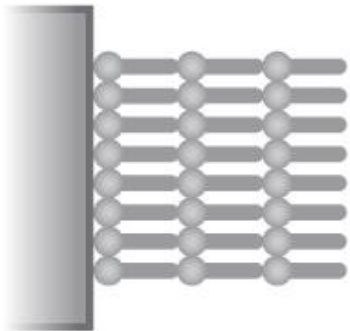
LB DEPOSITION ON A HYDROPHILIC SURFACE - 2ND LAYER



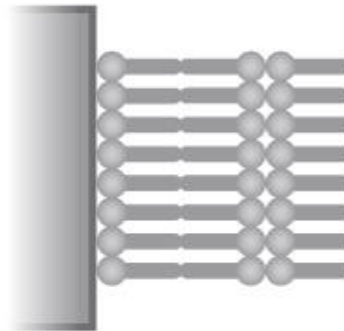
LB DEPOSITION ON A HYDROPHOBIC SURFACE



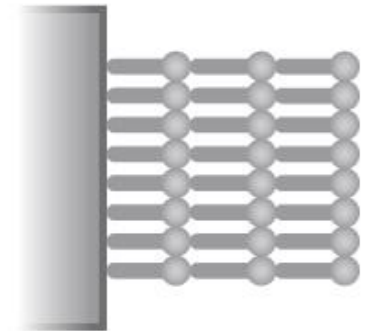
Z-TYPE ON A HYDROPHOBIC SURFACE



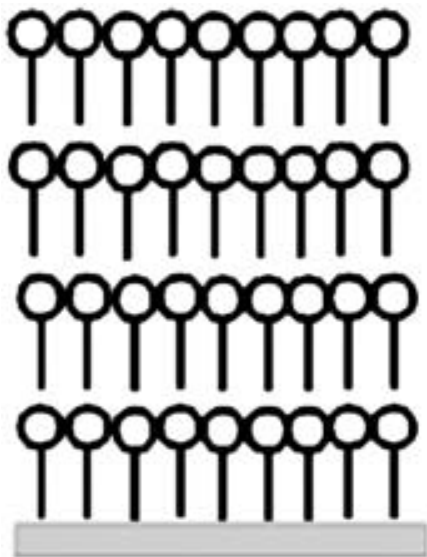
Y-TYPE ON A HYDROPHOBIC SURFACE



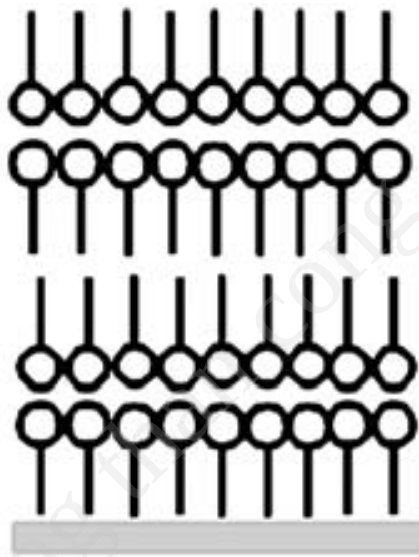
X-TYPE ON A HYDROPHOBIC SURFACE



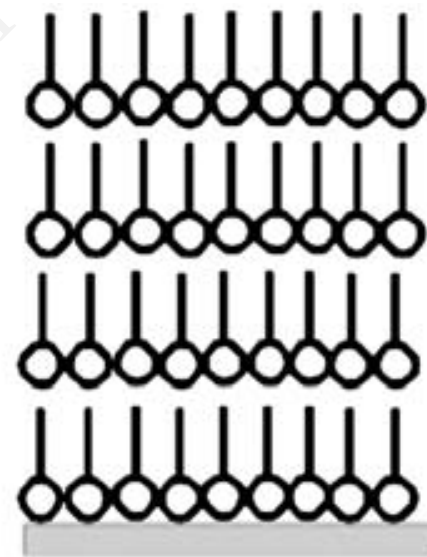
Various LB deposition possibilities on hydrophobic and hydrophilic substrates.



X-type



Y-type

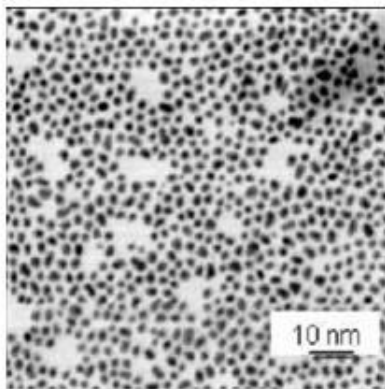
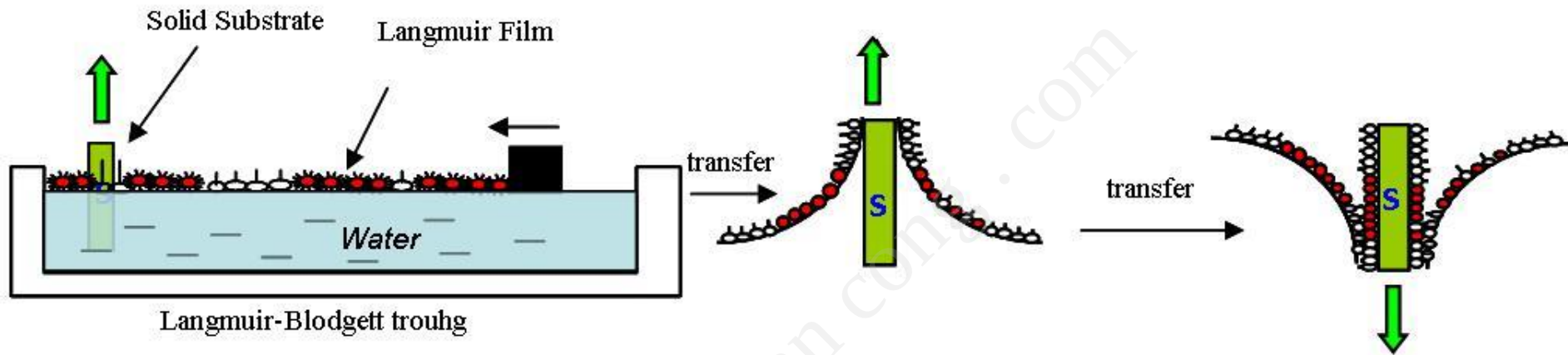


Z-type

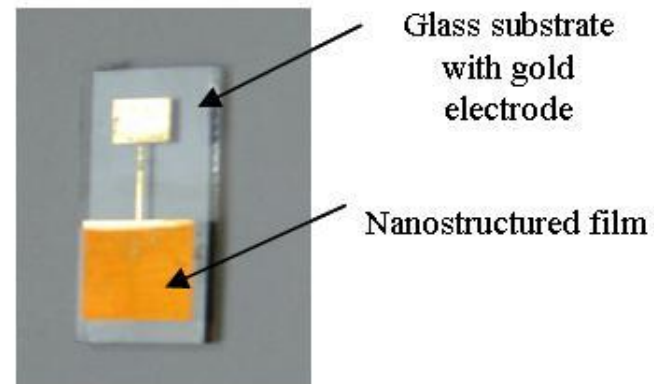
Deposition types of LB multilayers



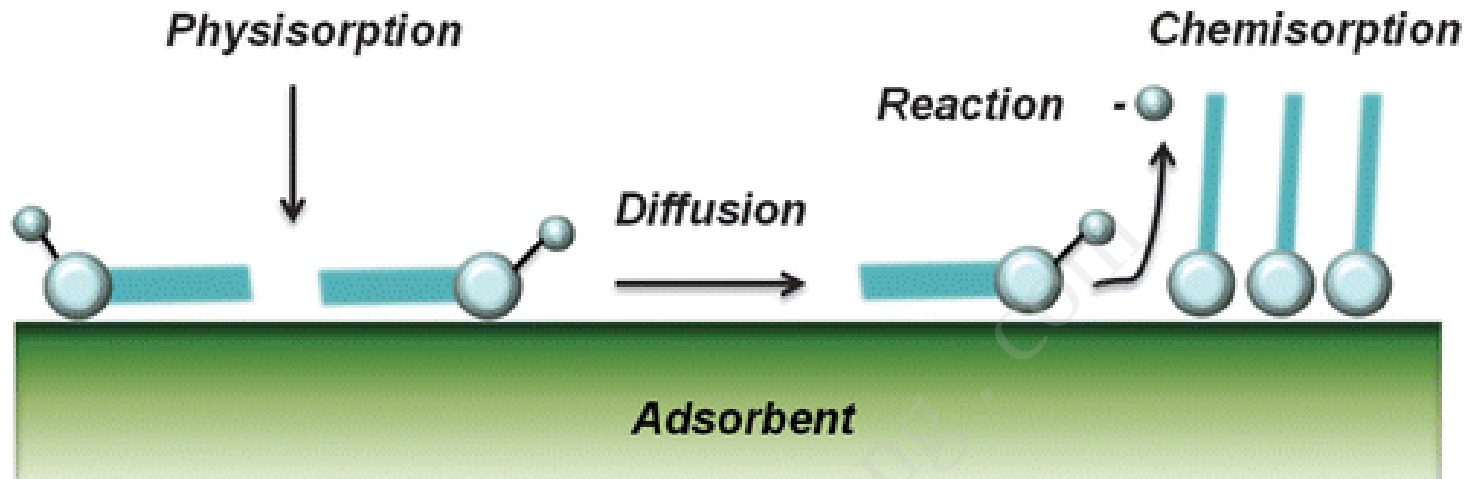
Langmuir-Blodgett film of silica-layer-bearing monolayer at the air-water interface



Nanoparticles
Monolayer



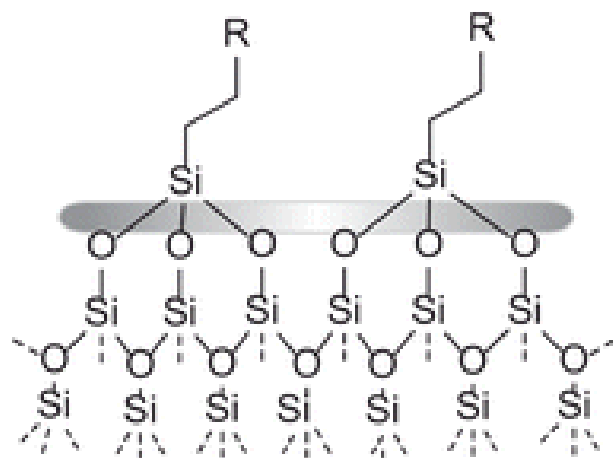
Langmuir-Blodgett films based on crown modified platinum nanoparticles



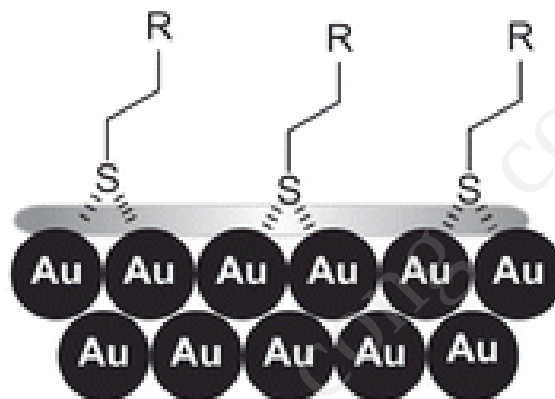
The processes leading to chemisorption.

- The first step is usually considered to be physisorption where the molecule adheres to the surface but is able to diffuse in the plane to a degree determined by the substrate temperature.
- The most frequent cases of chemisorbed molecules are those involving the bonding of organic molecules to metals, inorganic semiconductors or their oxides, and they are the basis of the development of a variety of self-assembled monolayers.
- The bonding is typically fully covalent, between oxygen or carbon atoms of the adsorbate and the surface atoms most commonly, or is essentially covalent through coordination between heteroatoms and inorganic surface atoms.

Layers Anchored with Covalent Bonds



Silicon oxide



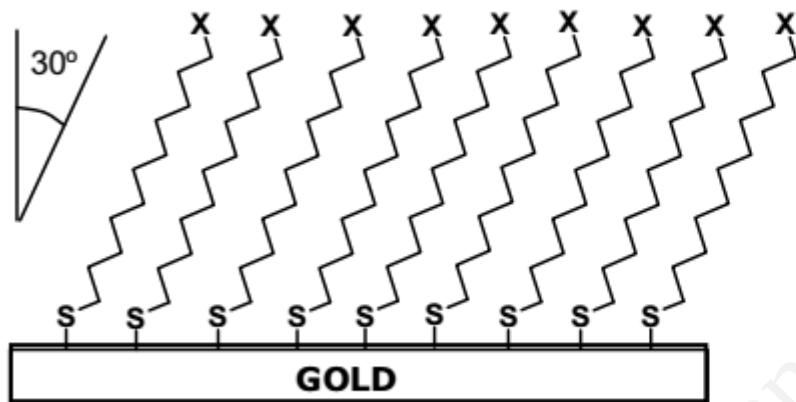
Gold



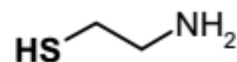
Organic or inorganic substrate

- Chemisorbed monolayers of organic compounds to the surfaces of oxides (silicon oxide), metals (for thiolates on gold) and organic surfaces where the term “grafting” is used frequently. The grey shaded region indicates the covalent bonds that are created during chemisorption.
- Electrochemical reduction of aromatic diazonium reagents leading a covalently bonded layer, anchored by a carbon-carbon bond. This scheme can also be applied to modify many other surfaces, including metals and semiconductors.

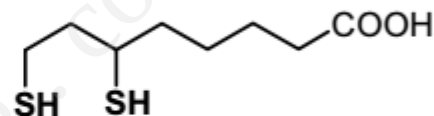
Metal Supports



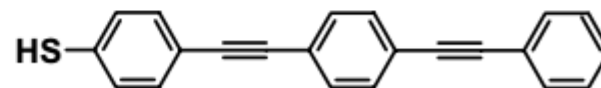
The conformation of an alkanethiol layer at a gold surface (X functional group)



Cysteamine



Dihydrolipoic acid



A molecular wire

Common thiol reagents for functionalization of a gold surface by sulfur chemisorption.

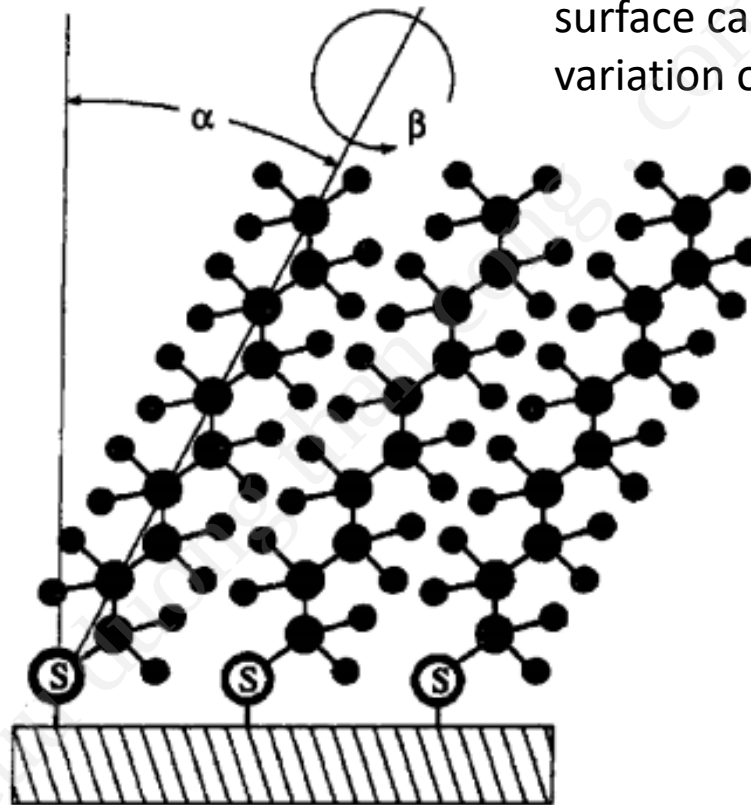
1/ Treatment of the metal surface to contain a high density of surface groups such as oxides or hydroxyl groups that will serve to form a bond with the modifying layer

2/ Direct reaction of the metal surface with a chemical agent (diazonium salts).

Self-assembled monolayer (SAM)

Noble metals
Semiconductors
Metal oxides

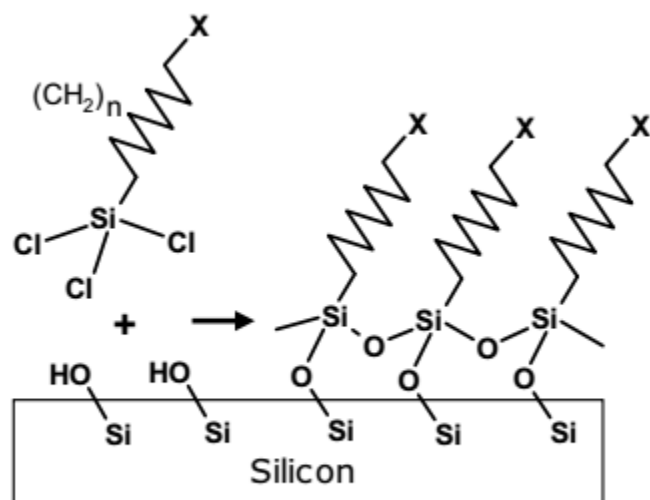
The chemistry and function of the surface can be controlled simply by variation of the tail group



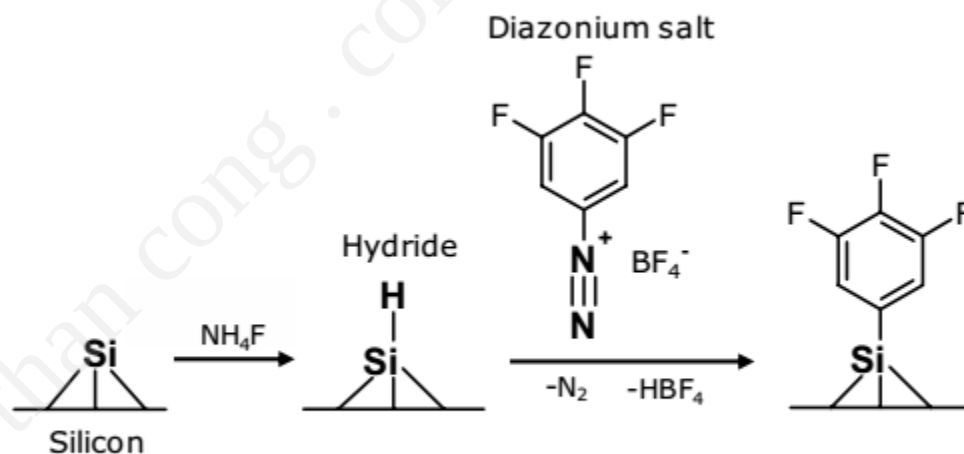
$$7.7 \cdot 10^{-10} \text{ mol/cm}^2$$

Schematic of a SAM composed of alkanethiolates chemisorbed at Au. The tilt (α) and twist (β) angles are shown here to define the precise orientation of the molecules on the surface

Semiconductor Supports

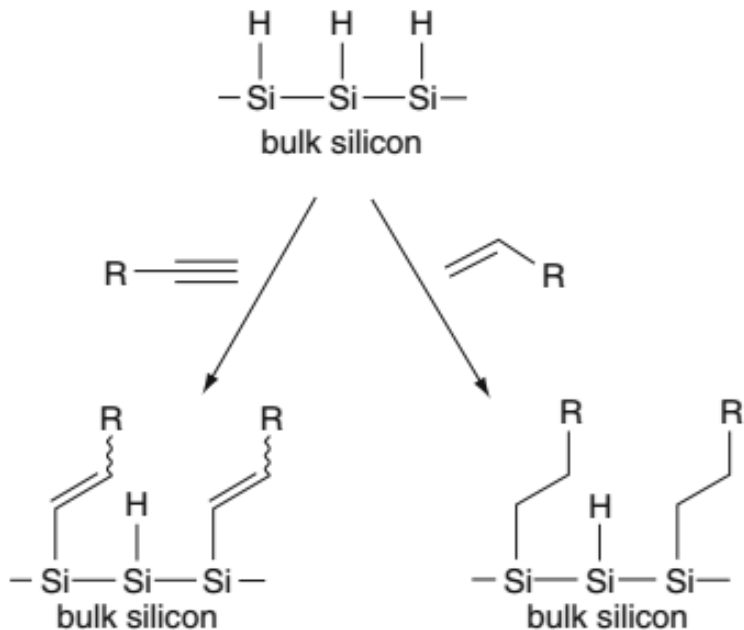


(A)

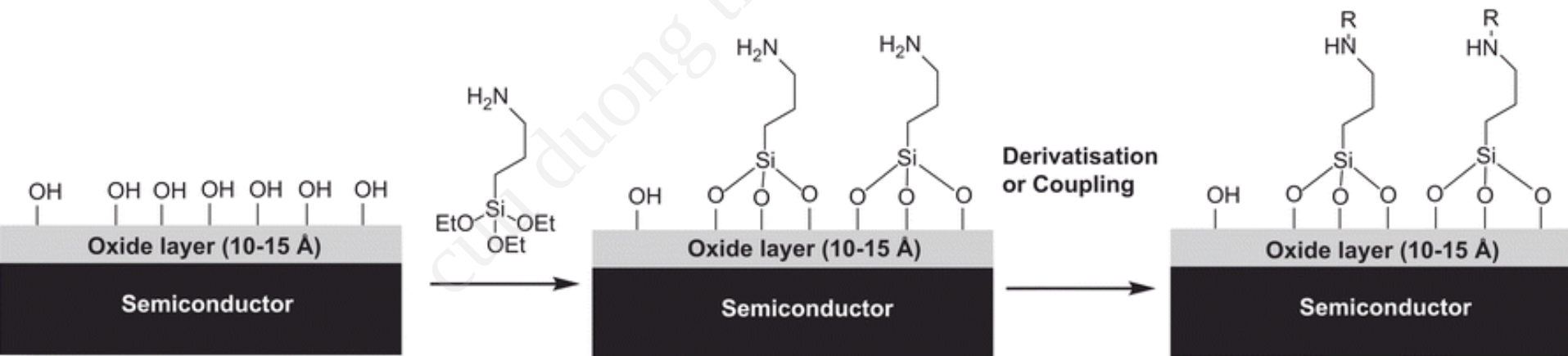


(B)

- (a) Modification of silicon surface by trichlorosilanes. X can be an amino group that is suitable for subsequent crosslinking.
- (b) Silicon surface modification by self-assembly of diazonium salts.



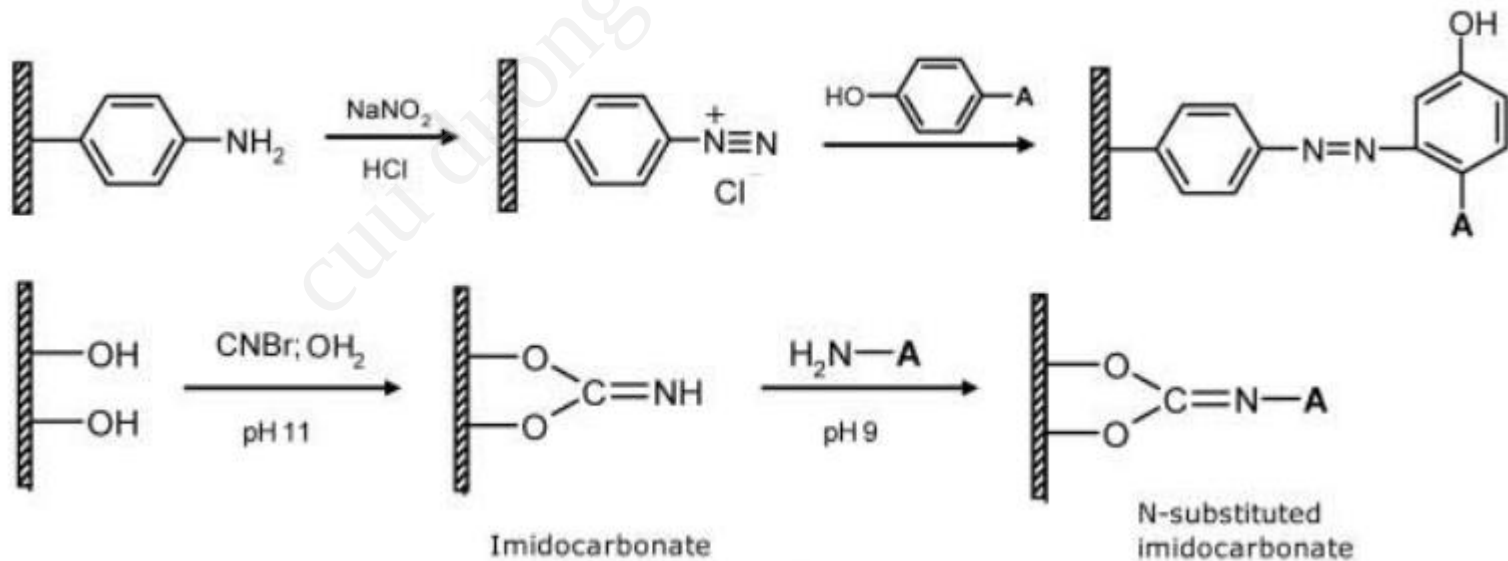
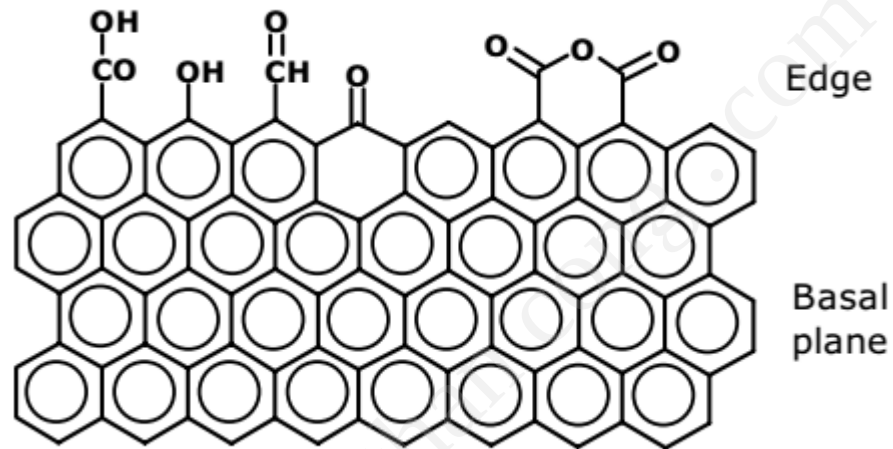
Covalent modification of Si: using either an alkyne (left) or alkene (right), a covalent bond results between the Si surface atoms and the modifying layer. These reactions can be activated with heat, light, or an added radical initiator



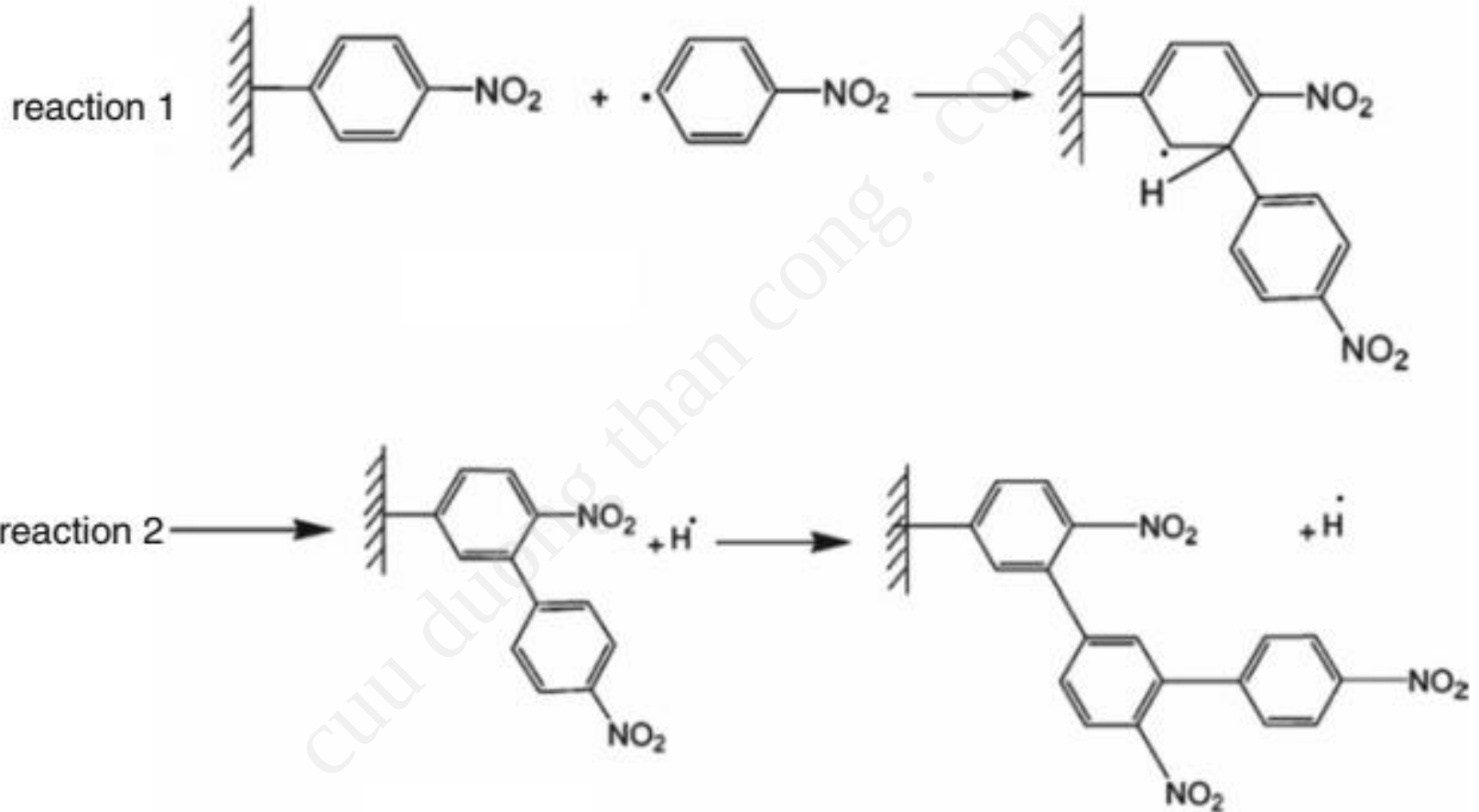
The chemical steps leading to the functionalisation of semiconductor surfaces by chemisorption of a siloxane followed by covalent modification.

Carbon Material Supports

Graphite structure



Multilayer Surface Modification



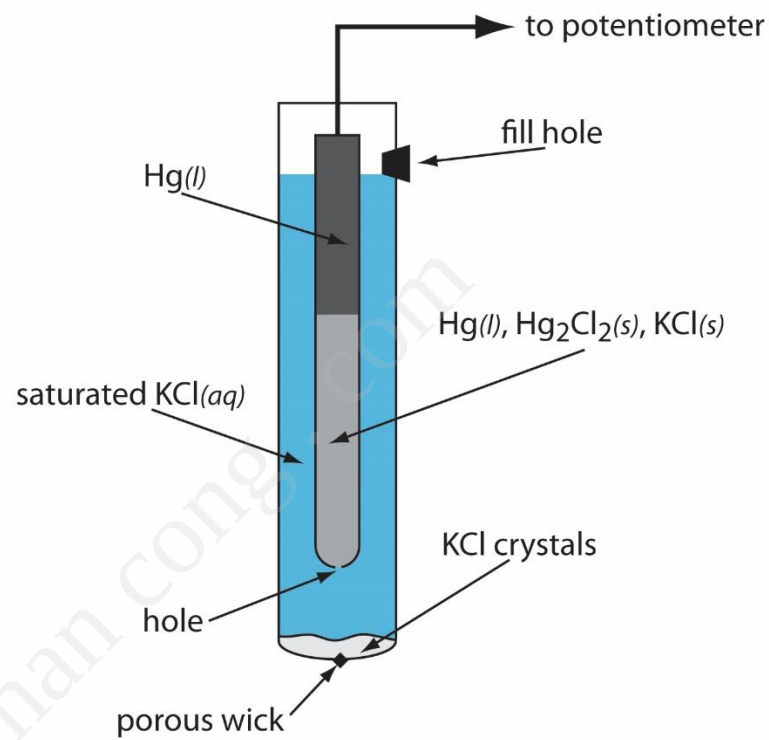
1 nm to >100 nm

Electropolymerization



Electrochemical cell





Platinum Electrodes

CE

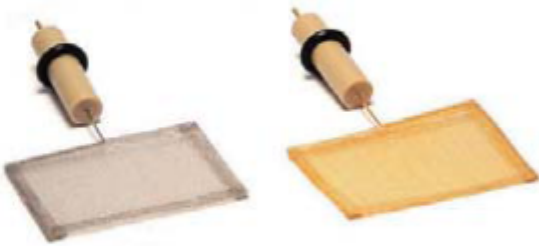


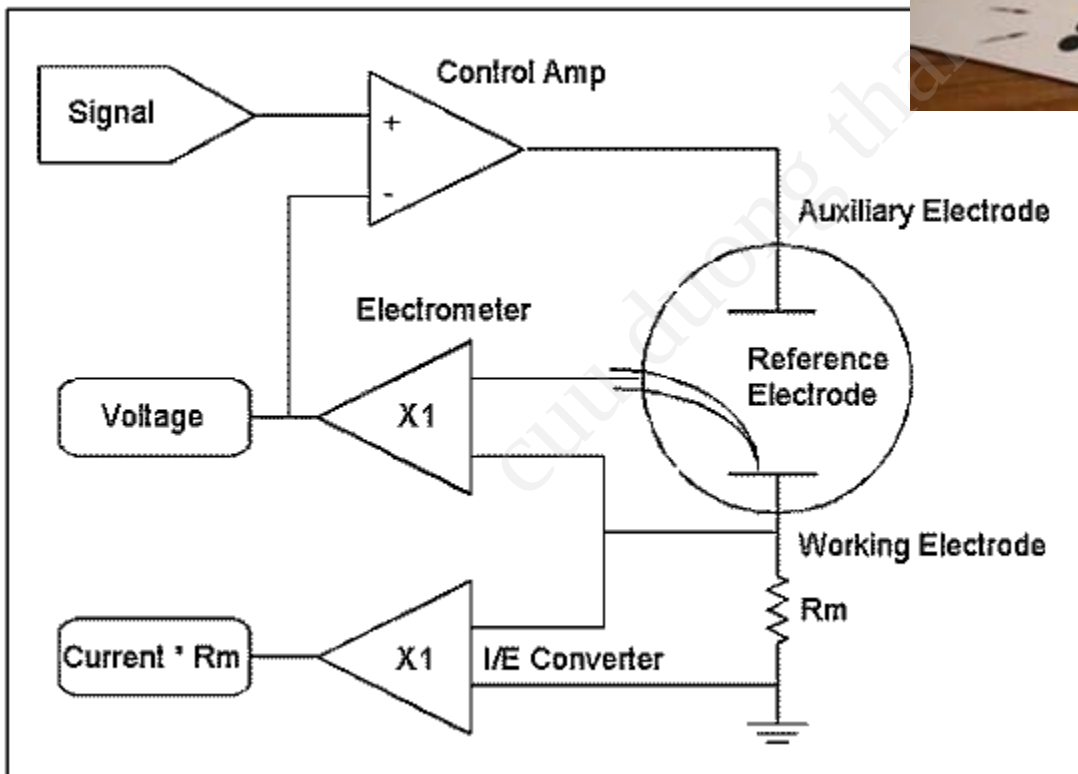
Pt Plate 6x8 mm, Glass body:

Shaft: 12 mm Ø x 110 mm L,
Cable: 1M included

Pt Wire 1mm Ø, Glass body:

Shaft: 12 mm Ø x 110 mm L,
Cable: 1M included

Platinum Gauze Electrode	Platinum Gauze Electrode & Gold Gauze Electrode
 • Part No. : PGE • for bulk electrolysis experiment • 50mmH * 39mm dia. * 50mmL wire	 • Part No. : 002250 • Part No. : 002251 • Pt gauze electrode • Au gauze electrode • 80mesh, 35*25mm • 100mesh, 35*25mm



Potentiostat Galvanostat

Single Channel Potentiostat/Galvanostat, WPG Series

Standard Type, WPG100



High Power Type, WPG100HP



Multi-Channel Potentiostat/Galvanostat, WMPG Series

Standard Type, WMPG1000S



Low Current Type, WMPG1000L



High Power Type, WMPG1000HP



Mid Power Type, WMPG1000M2



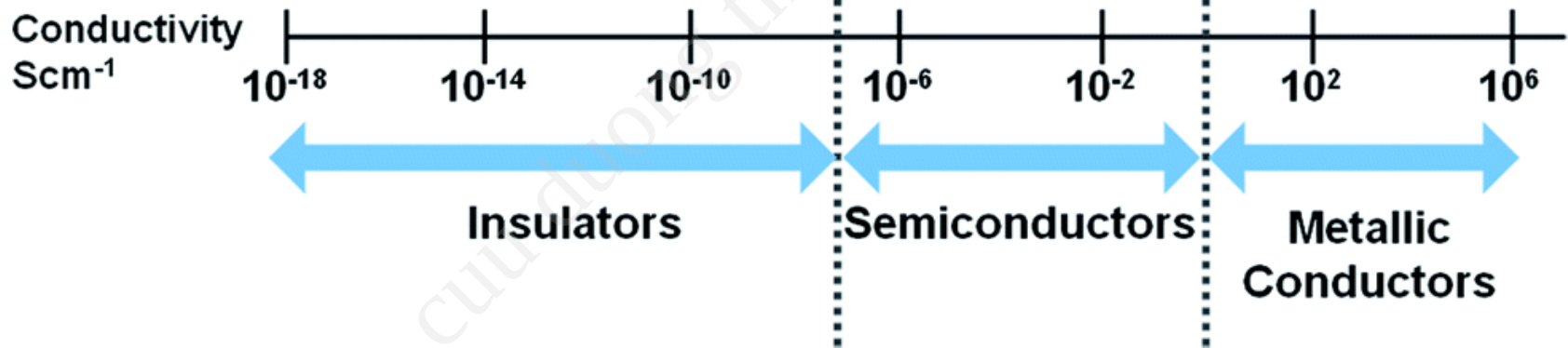


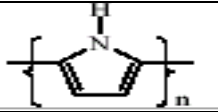
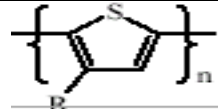
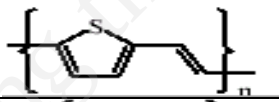
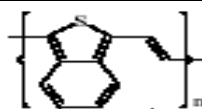
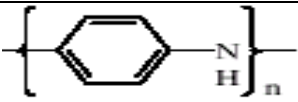


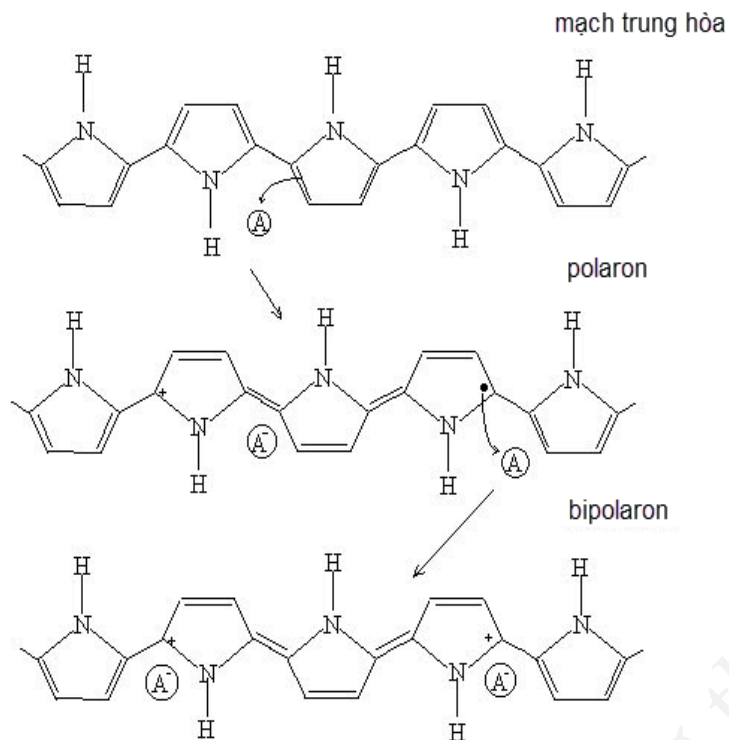
Conducting Polymers

← Uncharged (undoped) Charged (doped) →

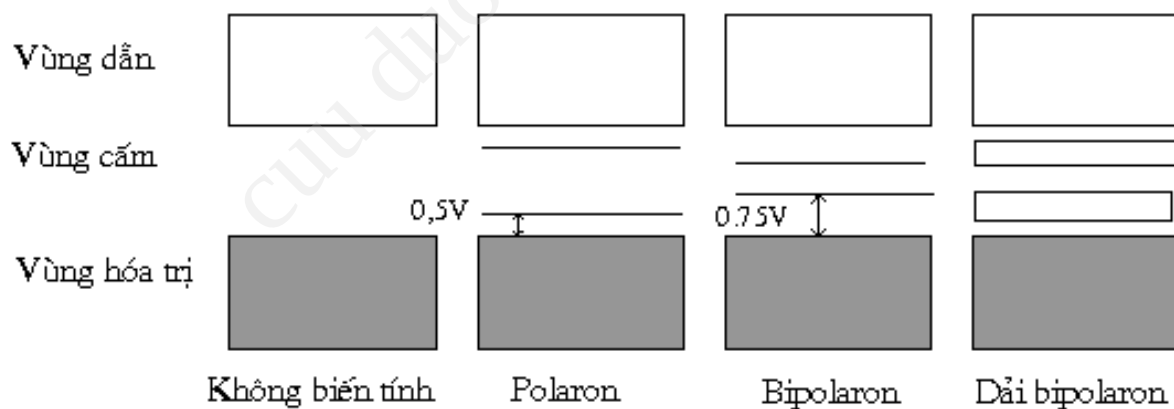
Electroactive Polymeric Composites/Blends



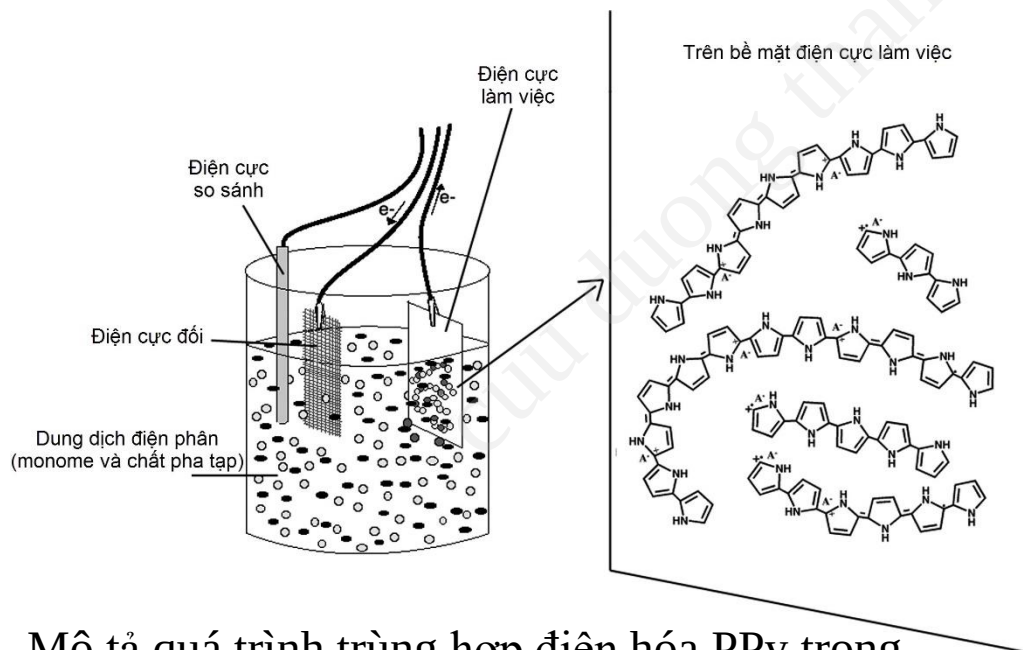
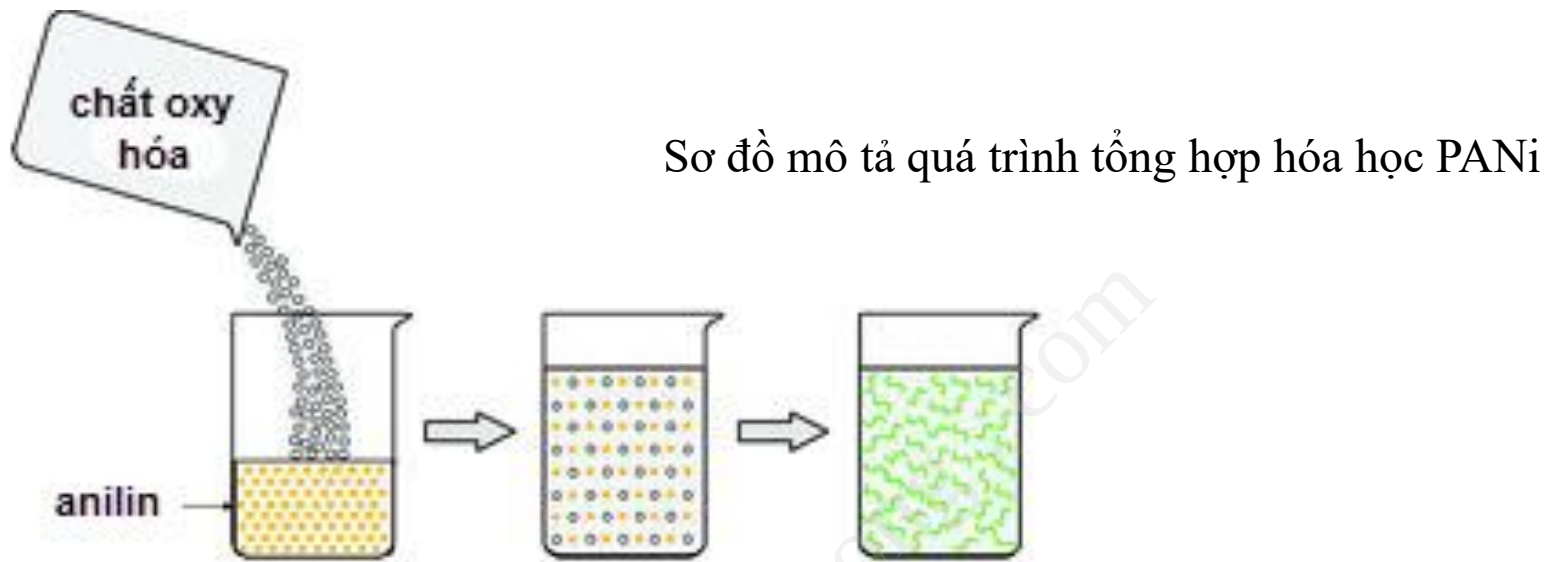
Polyme	Cấu trúc hóa học	Vật liệu pha tạp	Độ dẫn (S cm ⁻¹)
Polyacetylen	(CH) _n	I ₂ , Br ₂ , Li, Na, AsF ₅	10.000
Polypyrrol (PPy)		BF ₄ ⁻ , ClO ₄ ⁻	500-7.500
Polythiophen		BF ₄ ⁻ , ClO ₄ ⁻	100
Poly(3-alkylthiophen)		BF ₄ ⁻ , ClO ₄ ⁻	1.000- 10.000
Pol yphenylenesulfid		AsF ₅	500
Polyphylylenevinylen		AsF ₅	10.000
Polythienylenevinylen		AsF ₅	2.700
Polyphenylen		AsF ₅ , Li, Na	1.000
Polyisothianaphthen		BF ₄ ⁻ , ClO ₄ ⁻	50
Polyazulen		BF ₄ ⁻ , ClO ₄ ⁻	1
Polyfuran		BF ₄ ⁻ , ClO ₄ ⁻	100
Polyanilin (PANi)		HCl	200



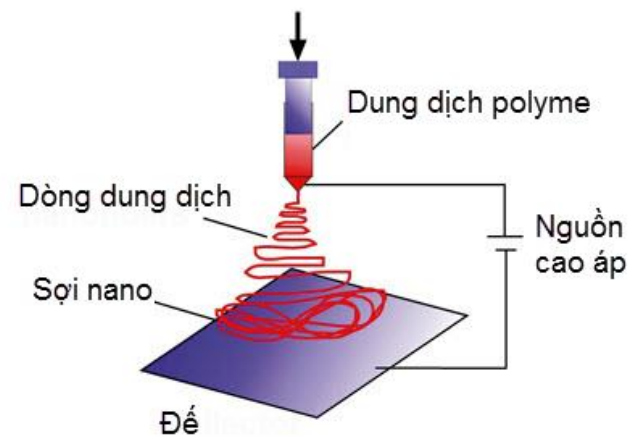
Trạng thái polaron và bipolaron của PPy



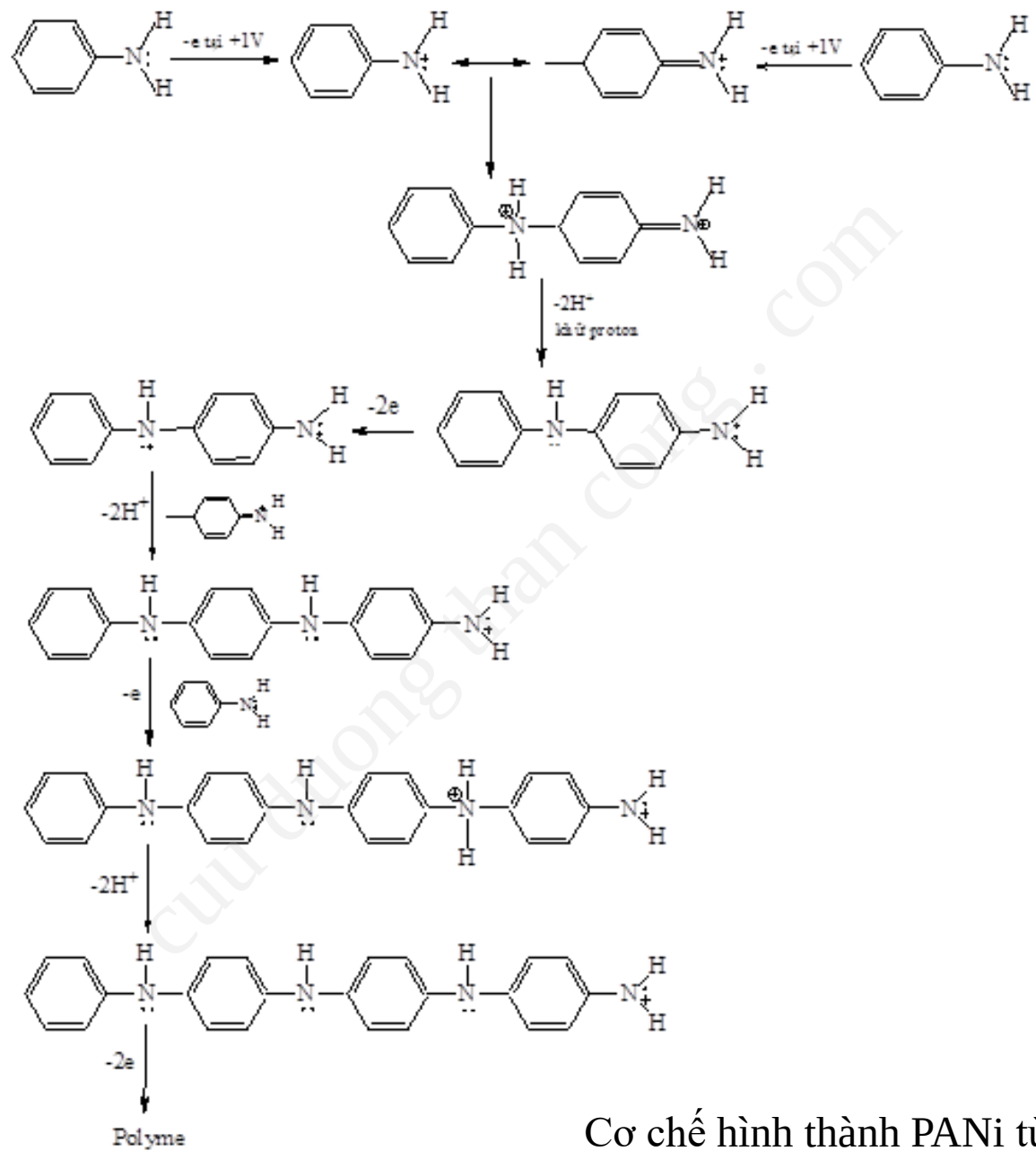
Sơ đồ vùng năng lượng của polyme dẫn điện trước và sau khi bị oxy hóa



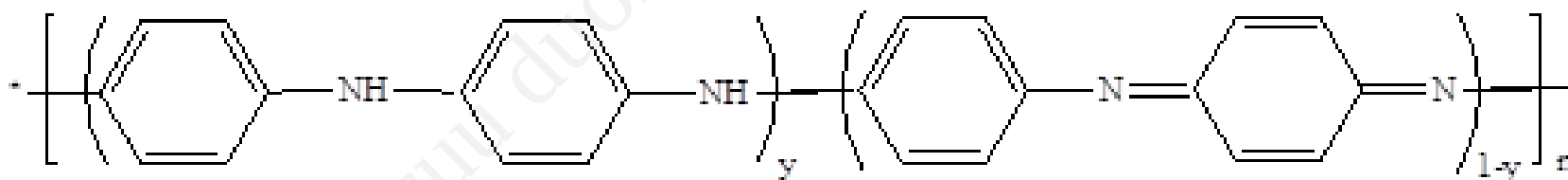
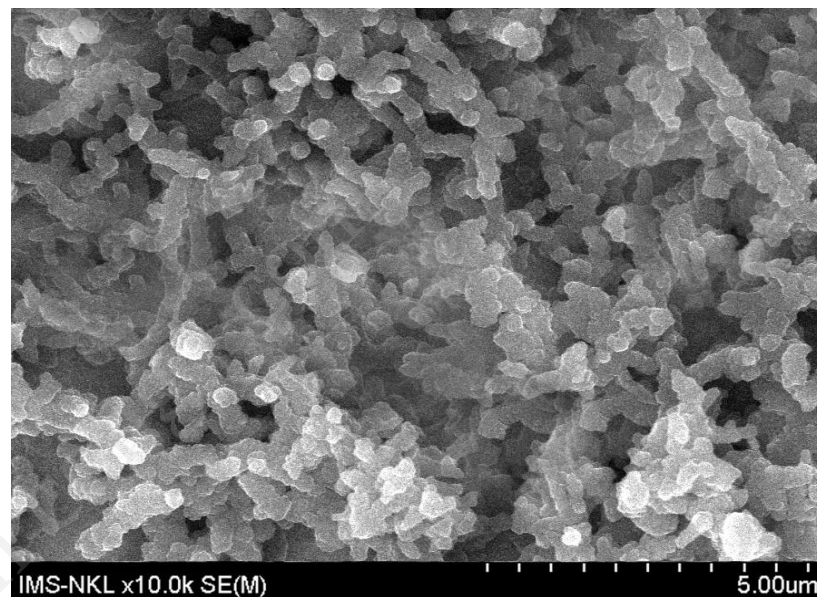
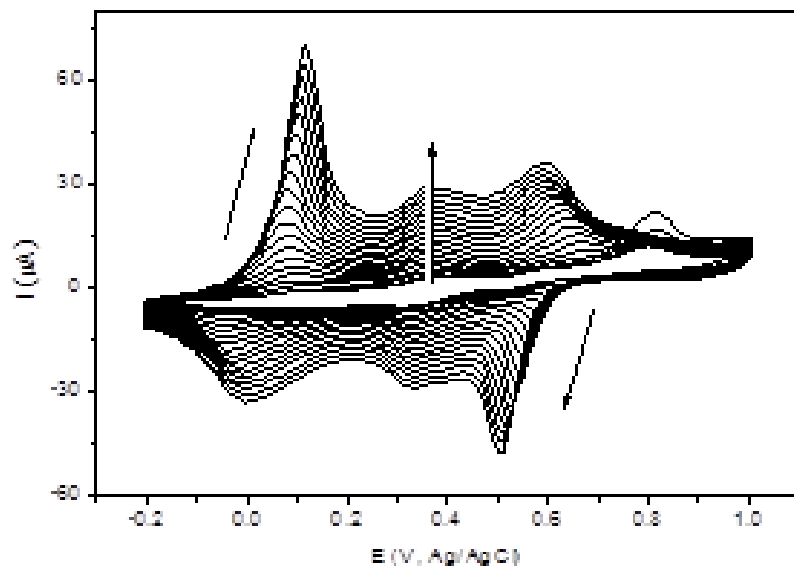
Mô tả quá trình trùng hợp điện hóa PPy trong hệ ba điện cực



Sơ đồ hệ phun tĩnh điện

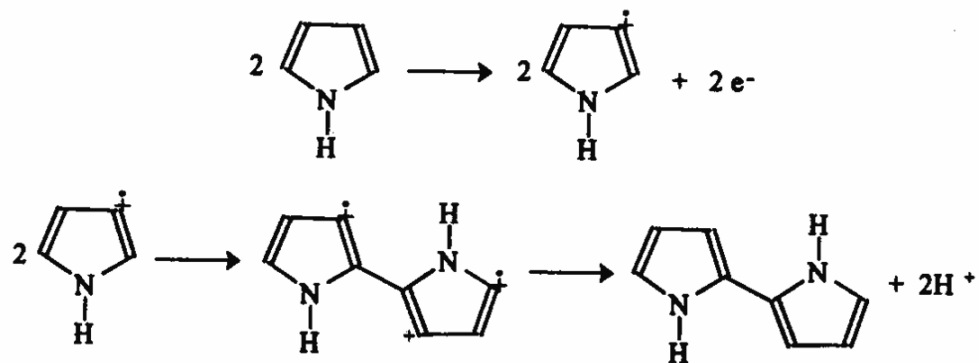


Cơ chế hình thành PANi từ Ani bằng phương pháp điện hóa

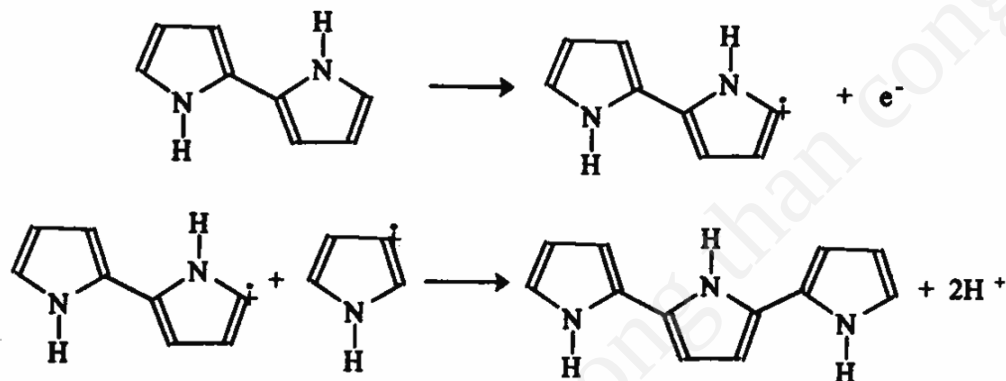


Công thức tổng quát của PANi
 (Khi $y = 1$: Leucoemeraldin; $y = 0,5$:
 Emeraldin; $y = 0$: Pernigranilin)

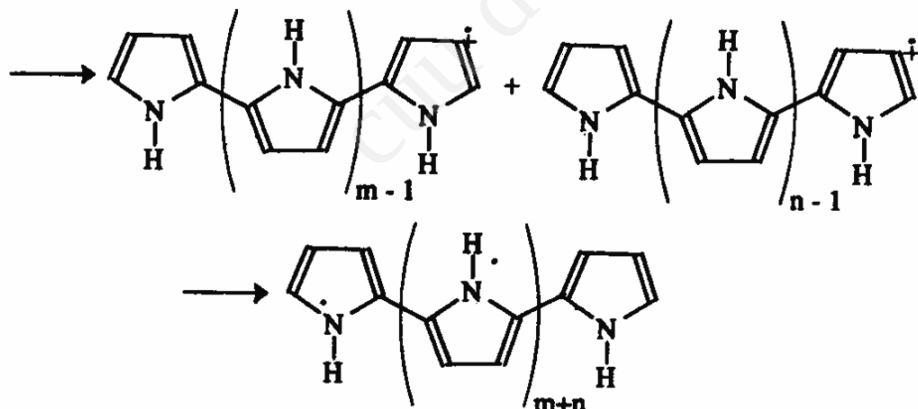
KHOI MÀO



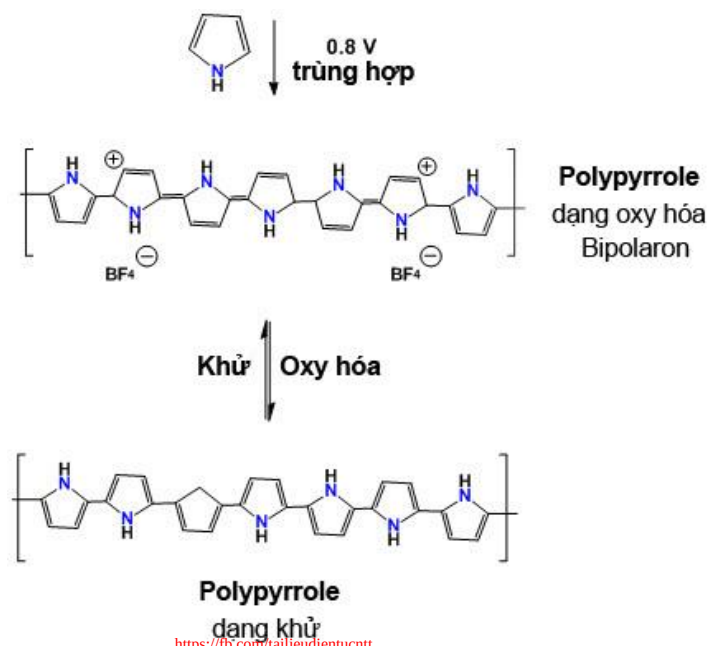
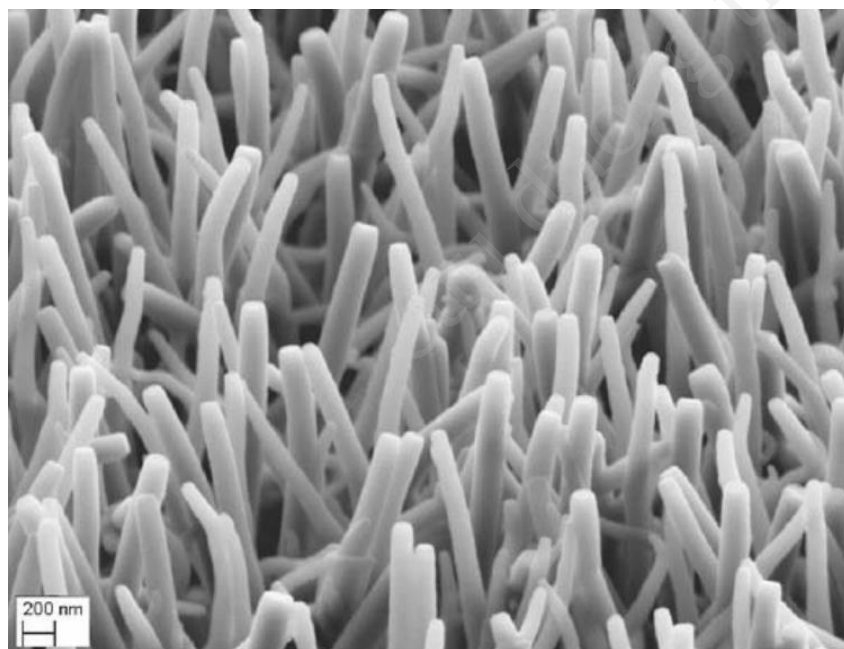
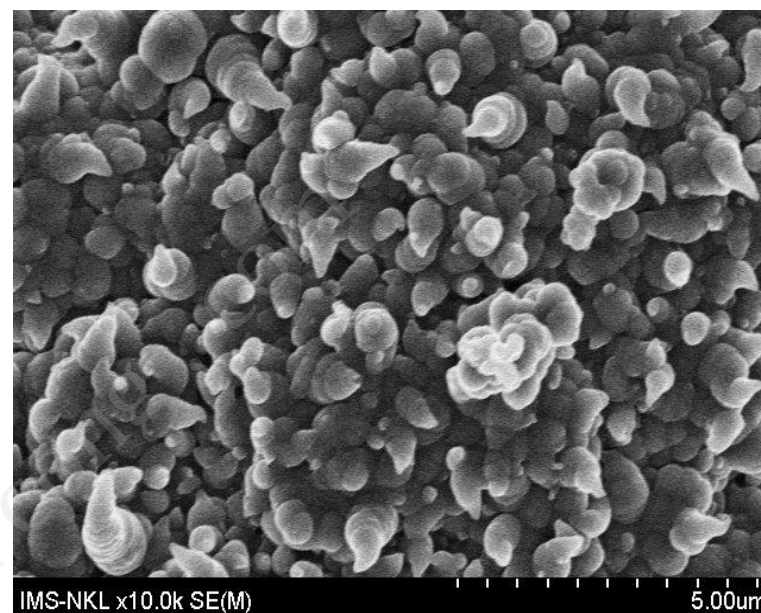
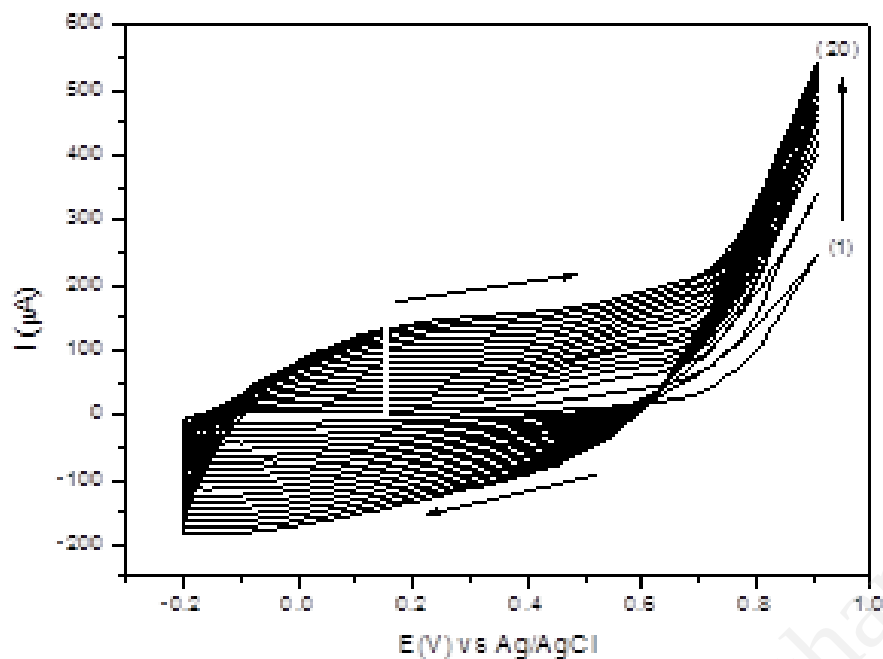
PHÁT TRIỂN MẠCH

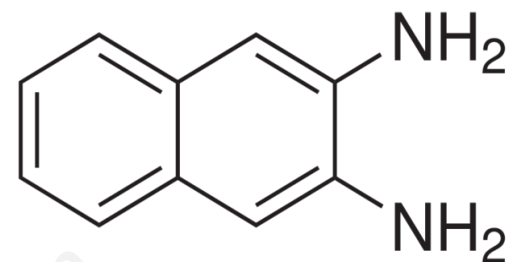
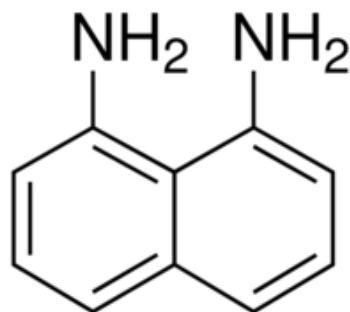
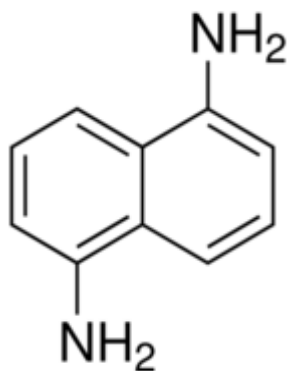


NGẮT MẠCH

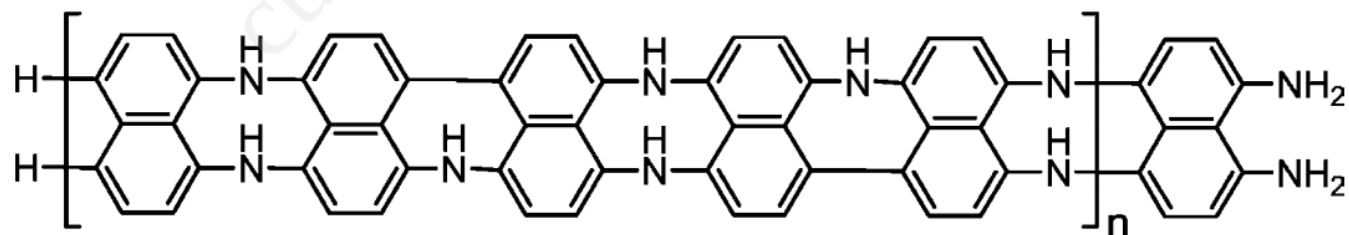
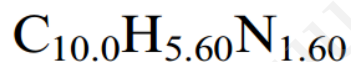
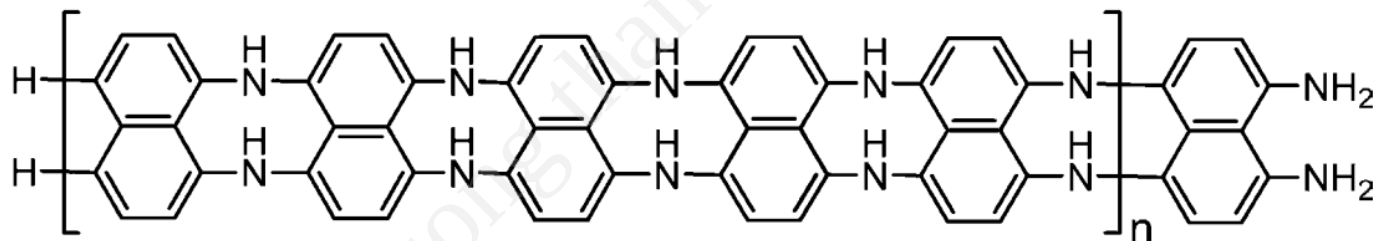
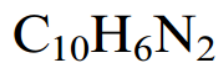


Cơ chế phản ứng trùng hợp PPy





Cấu trúc hóa học của (a) 1,5-; (b) 1,8-; (c) 2,3- diaminonaphthalen (DAN)



Các dạng cấu trúc của poly 1,8- diaminonaphthalen

